## Data Sheet

## FEATURES

## Dual transmitters

Dual input shared observation receiver
Maximum tunable transmitter synthesis bandwidth: 450 MHz
Maximum observation receiver bandwidth: $\mathbf{4 5 0} \mathbf{~ M H z}$
Fully integrated fractional-N RF synthesizers
Fully integrated clock synthesizer
Multichip phase synchronization for RF LO and baseband clocks
JESD204B datapath interface
Tuning range (center frequency): $75 \mathbf{~ M H z}$ to $6000 \mathbf{~ M H z}$

## APPLICATIONS

2G/3G/4G/5G macrocell base stations

## Active antenna systems

Massive multiple input, multiple output (MIMO)
Phased array radars
Electronic warfare
Military communications
Portable test equipment

## GENERAL DESCRIPTION

The ADRV9008-2 is a highly integrated, RF agile transmit subsystem offering dual-channel transmitters, an observation path receiver, integrated synthesizers, and digital signal processing functions. The IC delivers a versatile combination of high performance and low power consumption required by 2G/3G/4G/5G macrocell base stations, and active antenna applications.
The transmitters use an innovative direct conversion modulator that achieves multicarrier macrocell base station quality performance and low power. In $3 \mathrm{G} / 4 \mathrm{G}$ mode, the maximum transmitter large signal bandwidth is 200 MHz . In multicarrier
global system for mobile communications (MC GSM) mode, which has higher inband spurious-free dynamic range (SFDR), the maximum large signal bandwidth is 75 MHz .
The observation path consists of a wide bandwidth direct conversion receiver with state of the art dynamic range. The complete receive subsystem includes dc offset correction, quadrature correction, and digital filtering, thus eliminating the need for these functions in the digital baseband. Several auxiliary functions such as analog-to-digital converters (ADCs), digital-to-analog converters (DACs), and general-purpose inputs/outputs (GPIOs) for power amplifier (PA) and radio frequency (RF) front-end control are also integrated.
The fully integrated phase-locked loops (PLLs) provide high performance, low power fractional-N RF frequency synthesis for the transmitter and receiver sections. An additional synthesizer generates the clocks needed for the converters, digital circuits, and the serial interface. Special precautions have been taken to provide the isolation required in high performance base station applications. All voltage controlled oscillators (VCOs) and loop filter components are integrated.
The high speed JESD204B interface supports up to 12.288 Gbps lane rates, resulting in two lanes per transmitter in the widest bandwidth mode and two lanes for the observation path receiver in the widest bandwidth mode.

The core of the ADRV9008-2 can be powered directly from 1.3 V regulators and 1.8 V regulators and is controlled via a standard 4 -wire serial port. Comprehensive power-down modes are included to minimize power consumption in normal use. The ADRV 9008 - 2 is packaged in a $12 \mathrm{~mm} \times 12 \mathrm{~mm} 196$-ball chip scale ball grid array (CSP_BGA).

## ADRV9008-2

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## REVISION HISTORY

9/2018—Revision 0: Initial Version

FUNCTIONAL BLOCK DIAGRAM


## ADRV9008-2

## SPECIFICATIONS

Electrical characteristics at $\mathrm{VDDA1P3}^{1}=1.3 \mathrm{~V}, \mathrm{VDDD} 1 \mathrm{P} 3 \_\mathrm{DIG}=1.3 \mathrm{~V}, \mathrm{VDDA1P8}$ _TX $=1.8 \mathrm{~V}, \mathrm{~T}_{\mathrm{J}}=$ full operating temperature range. Local oscillator frequency $\left(\mathrm{f}_{\mathrm{LO}}\right)=1800 \mathrm{MHz}$, unless otherwise noted. The specifications in Table 1 are not de-embedded. Refer to the Typical Performance Characteristics section for input/output circuit path loss. The device configuration profile for the 75 MHz to 525 MHz frequency range is as follows: transmitter $=50 \mathrm{MHz} / 100 \mathrm{MHz}$ bandwidth (inphase quadrature (IQ) rate $=122.88 \mathrm{MHz}$ ), observation receiver $=100 \mathrm{MHz}$ bandwidth (IQ rate $=122.88 \mathrm{MHz}$ ), JESD204B rate $=9.8304 \mathrm{GSPS}$, and device clock $=245.76 \mathrm{MHz}$. Unless otherwise specified, the device configuration for all other frequency ranges is as follows: transmitter $=200 \mathrm{MHz} / 450 \mathrm{MHz}$ bandwidth (IQ rate $=491.52 \mathrm{MHz}$ ), observation receiver $=450 \mathrm{MHz}$ bandwidth $(\mathrm{IQ}$ rate $=491.52 \mathrm{MHz}), \mathrm{JESD} 204 \mathrm{~B}$ rate $=9.8304 \mathrm{GSPS}$, and device clock $=245.76 \mathrm{MHz}$.

Table 1.

| Parameter | Symbol | Min | Typ | Max | Unit | Test Conditions/Comments |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| TRANSMITTERS |  |  |  |  |  |  |
| Center Frequency |  | 75 |  | 6000 | MHz |  |
| Transmitter (Tx) <br> Synthesis Bandwidth (BW) |  |  |  | 450 | MHz |  |
| Transmitter Large Signal Bandwidth (3G/4G) |  |  |  | 200 | MHz |  |
| Transmitter Large Signal Bandwidth (MC GSM) |  |  |  | 75 | MHz | Low intermediate frequency (IF) mode |
| Peak-to-Peak Gain Deviation |  |  | 1.0 |  | dB | 450 MHz bandwidth, compensated by programmable finite impulse response (FIR) filter |
| Gain Slope |  |  | $\pm 0.1$ |  | dB | Any 20 MHz bandwidth span, compensated by programmable FIR filter |
| Deviation from Linear Phase |  |  | 1 |  | Degrees | 450 MHz bandwidth |
| Transmitter Attenuation Power Control Range |  | 0 |  | 32 | dB | Signal-to-noise ratio (SNR) maintained for attenuation between 0 dB and 20 dB |
| Transmitter Attenuation Power Control Resolution |  |  | 0.05 |  | dB |  |
| Transmitter Attenuation Integral Nonlinearity | INL |  | 0.1 |  | dB | For any 4 dB step |
| Transmitter Attenuation Differential Nonlinearity | DNL |  | $\pm 0.04$ |  | dB | Monotonic |
| Transmitter Attenuation <br> Serial Peripheral Interface 2 (SPI 2) Timing |  |  |  |  |  | See Figure 4 |
| Time from $\overline{C S}$ Going High to Change in Transmitter Attenuation | $\mathrm{tsch}^{\text {cher }}$ | 19.5 |  | 24 | ns |  |
| Time Between Consecutive Microattenuation Steps | $\mathrm{taCH}_{\text {A }}$ | 6.5 |  | 8.1 | ns | A large change in attenuation can be broken up into a series of smaller attenuation changes |
| Time Required to Reach Final Attenuation Value | toch |  |  | 800 | ns | Time required to complete the change in attenuation from start attenuation to final attenuation value |
| Maximum Attenuation Overshoot During Transition |  | -1.0 |  | +0.5 | dB |  |




| Parameter | Symbol | Min | Typ | Max |
| :--- | :--- | :--- | :--- | :--- |
| Second-Order Input <br> Intermodulation <br> Intercept Point | IIP2 | 62 | Unit | Test Conditions/Comments |


| Parameter | Symbol | Min | Typ | Max | Unit | Test Conditions/Comments |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Input Impedance Isolation |  |  | 100 |  | $\Omega$ | Differential (see Figure 266) |
| Transmitter 1 (Tx1) to Observation Receiver 1 (ORx1) and Transmitter 2 (Tx2) to Observation Receiver 2 (ORx2) |  |  | 100 |  | dB | $75 \mathrm{MHz}<\mathrm{f} \leq 600 \mathrm{MHz}$ |
|  |  |  | 65 |  | dB | $600 \mathrm{MHz}<\mathrm{f} \leq 5300 \mathrm{MHz}$ |
|  |  |  | 55 |  | dB | $5300 \mathrm{MHz}<\mathrm{f} \leq 6000 \mathrm{MHz}$ |
| Tx1 to ORx 2 and Tx2 to |  |  | 105 |  | dB | $75 \mathrm{MHz}<\mathrm{f} \leq 600 \mathrm{MHz}$ |
|  |  |  | 65 |  | dB | $600 \mathrm{MHz}<\mathrm{f} \leq 5300 \mathrm{MHz}$ |
|  |  |  | 55 |  | dB | $5300 \mathrm{MHz}<\mathrm{f} \leq 6000 \mathrm{MHz}$ |
| LO SYNTHESIZER |  |  |  |  |  |  |
| LO Frequency Step |  |  | 2.3 |  | Hz | 1.5 GHz to $2.8 \mathrm{GHz}, 76.8 \mathrm{MHz}$ phase frequency detector (PFD) frequency |
| LO Spur |  |  | -85 |  | dBC | Excludes integer boundary spurs |
| 75 MHz LO |  |  | 0.014 |  | ${ }^{\circ} \mathrm{rms}$ | Narrow PLL loop bandwidth $\text { ( } 50 \mathrm{kHz} \text { ) }$ |
| 1900 MHz LO |  |  | 0.2 |  | ${ }^{\circ} \mathrm{rms}$ | Narrow PLL loop bandwidth ( 50 kHz ) |
| 3800 MHz LO |  |  | 0.36 |  | ${ }^{\circ} \mathrm{rms}$ | Wide PLL loop bandwidth (300 kHz) |
| 5900 MHz LO |  |  | 0.54 |  | ${ }^{\circ} \mathrm{rms}$ | Wide PLL loop bandwidth (300 kHz) |
| Spot Phase Noise |  |  |  |  |  |  |
| 75 MHz LO |  |  |  |  |  | Narrow PLL loop bandwidth |
| 10 kHz Offset |  |  | -126.5 |  | $\mathrm{dBc} / \mathrm{Hz}$ |  |
| 100 kHz Offset |  |  | -132.8 |  | $\mathrm{dBc} / \mathrm{Hz}$ |  |
| 1 MHz Offset |  |  | -150.1 |  | $\mathrm{dBc} / \mathrm{Hz}$ |  |
| 10 MHz Offset |  |  | -150.7 |  | $\mathrm{dBc} / \mathrm{Hz}$ |  |
| 1900 MHz LO |  |  |  |  |  | Narrow PLL loop bandwidth |
| 100 kHz Offset |  |  | -100 |  | $\mathrm{dBc} / \mathrm{Hz}$ |  |
| 200 kHz Offset |  |  | -115 |  | $\mathrm{dBc} / \mathrm{Hz}$ |  |
| 400 kHz Offset |  |  | -120 |  | $\mathrm{dBc} / \mathrm{Hz}$ |  |
| 600 kHz Offset |  |  | -129 |  | $\mathrm{dBc} / \mathrm{Hz}$ |  |
| 800 kHz Offset |  |  | -132 |  | $\mathrm{dBc} / \mathrm{Hz}$ |  |
| 1.2 MHz Offset |  |  | -135 |  | $\mathrm{dBc} / \mathrm{Hz}$ |  |
| 1.8 MHz Offset |  |  | -140 |  | $\mathrm{dBc} / \mathrm{Hz}$ |  |
| 6 MHz Offset |  |  | -150 |  | $\mathrm{dBc} / \mathrm{Hz}$ |  |
| 10 MHz Offset |  |  | -153 |  | $\mathrm{dBc} / \mathrm{Hz}$ |  |
| 3800 MHz LO |  |  |  |  |  | Wide PLL loop bandwidth |
| 100 kHz Offset |  |  | -104 |  | $\mathrm{dBc} / \mathrm{Hz}$ |  |
| 1.2 MHz Offset |  |  | -125 |  | $\mathrm{dBc} / \mathrm{Hz}$ |  |
| 10 MHz Offset |  |  | -145 |  | $\mathrm{dBc} / \mathrm{Hz}$ |  |
| 5900 MHz LO |  |  |  |  |  | Wide PLL loop bandwidth |
| 100 kHz Offset |  |  | -99 |  | $\mathrm{dBc} / \mathrm{Hz}$ |  |
| 1.2 MHz Offset |  |  | -119.7 |  | $\mathrm{dBc} / \mathrm{Hz}$ |  |
| 10 MHz Offset |  |  | -135.4 |  | $\mathrm{dBc} / \mathrm{Hz}$ |  |
| LO PHASE SYNCHRONIZATION |  |  |  |  |  |  |
| Phase Deviation |  |  | 1.6 |  | $\mathrm{ps} /{ }^{\circ} \mathrm{C}$ | Change in LO delay per temperature change |


| Parameter | Symbol | Min | Typ | Max | Unit | Test Conditions/Comments |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| EXTERNAL LO INPUT <br> Input Frequency <br> Input Signal Power <br> External LO Input Signal Differential <br> Phase Error <br> Amplitude Error Duty Cycle Error Even-Order Harmonics | $\mathrm{f}_{\text {EXTLO }}$ | $\begin{aligned} & 300 \\ & 0 \end{aligned}$ | 3 <br> 6 | 8000 <br> 12 <br> 3.6 <br> 1 <br> 2 $-50$ | MHz <br> dBm <br> dBm <br> dBm <br> ps <br> dB <br> \% <br> dBc | Input frequency must be $2 x$ the desired LO frequency $50 \Omega$ matching at the source $\mathrm{f}_{\mathrm{ExTL}} \leq 2 \mathrm{GHz}$, add $0.5 \mathrm{dBm} / \mathrm{GHz}$ above 2 GHz $\mathrm{f}_{\mathrm{ExTLO}}=8 \mathrm{GHz}$ <br> To ensure adequate QEC |
| CLOCK SYNTHESIZER <br> Integrated Phase Noise 1966.08 MHz LO <br> Spot Phase Noise 1966.08 MHz LO 100 kHz Offset 1 MHz Offset 10 MHz Offset |  |  | $0.4$ $\begin{aligned} & -109 \\ & -129 \\ & -149 \end{aligned}$ |  | ${ }^{\circ} \mathrm{rms}$ <br> $\mathrm{dBc} / \mathrm{Hz}$ <br> $\mathrm{dBc} / \mathrm{Hz}$ <br> $\mathrm{dBc} / \mathrm{Hz}$ | 1 kHz to 100 MHz PLL optimized for close in phase noise |
| REFERENCE CLOCK (REF_CLK_IN $\pm$ ) Frequency Range Signal Level |  | $\begin{aligned} & 10 \\ & 0.3 \end{aligned}$ |  | $\begin{aligned} & 1000 \\ & 2.0 \end{aligned}$ | $\begin{aligned} & \mathrm{MHz} \\ & \mathrm{~V} p-\mathrm{p} \end{aligned}$ | AC-coupled, common-mode voltage $\left(\mathrm{V}_{\mathrm{CM}}\right)=618 \mathrm{mV}$, for best spurious performance, use <1 V p-p input clock |
| AUXILIARY CONVERTERS <br> ADC <br> Resolution <br> Input Voltage <br> Minimum <br> Maximum <br> DAC <br> Resolution <br> Output Voltage <br> Minimum <br> Maximum <br> Output Drive Capability |  |  | 12 <br> 0.05 <br> VDDA <br> 3P3-0.05 <br> 10 <br> 0.7 <br> VDDA <br> 3P3-0.3 <br> 10 |  | Bits <br> V <br> V <br> Bits <br> V <br> V <br> mA | Includes four offset levels $\begin{aligned} & 1 \mathrm{~V} \mathrm{~V}_{\text {REF }} \\ & 2.5 \mathrm{~V}_{\mathrm{REF}} \end{aligned}$ |
| DIGITAL SPECIFICATIONS (CMOS)—SDIO, SDO, SCLK, $\overline{C S}$ GPIO_x, TXx_ENABLE, ORXx_ENABLE Logic Inputs Input Voltage High Level <br> Low Level <br> Input Current |  | VDD_ <br> INTERFACE $\times 0.8$ <br> 0 |  | VDD_INTERFACE <br> VDD_ <br> INTERFACE $\times 0.2$ | V <br> V |  |

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| Parameter | Symbol | Min | Typ | Max | Unit | Test Conditions/Comments |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| High Level |  | -10 |  | +10 | $\mu \mathrm{A}$ |  |
| Low Level |  | -10 |  | +10 | $\mu \mathrm{A}$ |  |
| Logic Outputs |  |  |  |  |  |  |
| Output Voltage |  |  |  |  |  |  |
| High Level |  | VDD_ <br> INTERFACE $\times 0.8$ |  |  | V |  |
| Low Level |  |  |  | VDD_ <br> INTERFACE $\times 0.2$ | V |  |
| Drive Capability |  |  | 3 |  | mA |  |
| DIGITAL SPECFICATIONS <br> (CMOS)—GPIO_3p3_x |  |  |  |  |  |  |
| Logic Inputs |  |  |  |  |  |  |
| Input Voltage |  |  |  |  |  |  |
| High Level |  | $\begin{aligned} & \text { VDDA_3P3 } \\ & \times 0.8 \end{aligned}$ |  | $\begin{aligned} & \text { VDDA_ } \\ & 3 P 3 \end{aligned}$ | V |  |
| Low Level |  | 0 |  | $\begin{aligned} & \text { VDDA } \\ & 3 P 3 \times 0.2 \end{aligned}$ | V |  |
| Input Current |  |  |  |  |  |  |
| High Level |  | -10 |  | +10 | $\mu \mathrm{A}$ |  |
| Low Level |  | -10 |  | +10 | $\mu \mathrm{A}$ |  |
| Logic Outputs |  |  |  |  |  |  |
| Output Voltage |  |  |  |  |  |  |
| High Level |  | $\begin{aligned} & \text { VDDA } \\ & 3 P 3 \times 0.8 \end{aligned}$ |  |  | V |  |
| Low Level |  |  |  | $\begin{aligned} & \text { VDDA }_{-} \\ & 3 \mathrm{P} 3 \times 0.2 \end{aligned}$ | V |  |
| Drive Capability |  |  | 4 |  | mA |  |
| DIGITAL SPECIFICATIONS (LVDS) |  |  |  |  |  |  |
| Logic Inputs $\frac{(\text { SYSREF_IN } \pm,}{\text { SYNCINx } \pm \text { ) }}$ |  |  |  |  |  |  |
| Input Voltage Range |  | 825 |  | 1675 | mV | Each differential input in the pair |
| Input Differential Voltage Threshold |  | -100 |  | +100 | mV |  |
| Receiver Differential Input Impedance |  |  | 100 |  | $\Omega$ | Internal termination enabled |
| $\frac{\text { Logic Outputs }}{\text { (SYNCOUTx } \pm \text { ) }}$ |  |  |  |  |  |  |
| Output Voltage |  |  |  |  |  |  |
| High |  |  |  | 1375 | mV |  |
| Low |  | 1025 |  |  | mV |  |
| Output Differential Voltage |  |  | 225 |  | mV | Programmable in 75 mV steps |
| Output Offset Voltage |  |  | 1200 |  | mV |  |
| SPI TIMING |  |  |  |  |  | See the UG-1295 for more information. |
| SCLK Period | $\mathrm{t}_{\text {cP }}$ | 20 |  |  | ns |  |
| SCLK Pulse Width | $\mathrm{t}_{\mathrm{MP}}$ | 10 |  |  | ns |  |
| $\overline{\mathrm{CS}}$ Setup to First SCLK Rising Edge | $\mathrm{t}_{\mathrm{sc}}$ | 3 |  |  | ns |  |
| Last SCLK Falling Edge to $\overline{\mathrm{CS}}$ Hold | $\mathrm{t}_{\mathrm{HC}}$ | 0 |  |  | ns |  |
| SDIO Data Input Setup to SCLK | $\mathrm{t}_{\text {s }}$ | 2 |  |  | ns |  |


| Parameter | Symbol | Min | Typ | Max | Unit | Test Conditions/Comments |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| SDIO Data Input Hold to SCLK | $\mathrm{tH}_{\mathrm{H}}$ | 0 |  |  | ns |  |
| SCLK Rising Edge to Output Data Delay (3-Wire or 4-Wire Mode) | $\mathrm{t}_{\mathrm{co}}$ | 3 |  | 8 | ns |  |
| Bus Turnaround Time, Read After Bits per Pixel (BPP) Drives Last Address Bit | $\mathrm{t}_{\mathrm{HzM}}$ | $\mathrm{t}_{\mathrm{H}}$ |  | $\mathrm{t}_{\text {co }}$ | ns |  |
| Bus Turnaround Time, Read After ADRV9008-2 Drives Last Data Bit | thzs | 0 |  | tco | ns |  |
| JESD204B DATA OUTPUT <br> TIMING |  |  |  |  |  | AC-coupled |
| Unit Interval | UI | 81.38 |  | 320 | ps |  |
| Data Rate per Channel Nonreturn to Zero (NRZ) |  | 3125 |  | 12,288 | Mbps |  |
| Rise Time | $\mathrm{t}_{\mathrm{R}}$ | 24 | 39.5 |  | ps | 20\% to $80 \%$ in $100 \Omega$ load |
| Fall Time | $\mathrm{t}_{\mathrm{F}}$ | 24 | 39.4 |  | ps | $20 \%$ to $80 \%$ in $100 \Omega$ load |
| Output Common-Mode Voltage | $V_{\text {CM }}$ | 0 |  | 1.8 | V | AC-coupled |
| Differential Output Voltage | $V_{\text {DIFF }}$ | 360 | 600 | 770 | mV |  |
| Short-Circuit Current | $\mathrm{I}_{\text {DSHORT }}$ | -100 |  | +100 | mA |  |
| Differential Termination Impedance |  | 80 | 94.2 | 120 | $\Omega$ |  |
| Total Jitter |  |  | 15.13 |  | ps | Bit error rate $(\mathrm{BER})=10^{-15}$ |
| Uncorrelated Bounded High Probability Jitter | UBHPJ |  | 0.56 |  | ps |  |
| Duty Cycle Distortion | DCD |  | 0.369 |  | ps |  |
| SYSREF_IN $\pm$ Setup Time to REF_CLK_IN $\pm$ |  | 2.5 |  |  | ns | See Figure 2 |
| SYSREF_IN $\pm$ Hold Time to REF_CLK_IN $\pm$ |  | -1.5 |  |  | ns | See Figure 2 |
| Latency | tLAT_FRM |  |  |  |  | REF_CLK_IN $\pm=245.76 \mathrm{MHz}$ |
|  |  |  | 116.5 |  | Clock cycles | Observation receiver bandwidth $=$ 450 MHz , IQ rate $=491.52 \mathrm{MHz}$, lane rate $=9830.4 \mathrm{MHz}$, number of converters $(M)=4$, number of lanes $(\mathrm{L})=2$, converter resolution $(\mathrm{N})=16$, number of samples per converter $(S)=1$ |
|  |  |  | 237.02 |  | ns |  |
|  |  |  | $89.4$ |  | Clock cycles | $\begin{aligned} & \text { Observation receiver bandwidth = } \\ & 200 \mathrm{MHz}, \mathrm{IQ} \text { rate }=245.76 \mathrm{MHz} \text {, lane } \\ & \text { rate }=9830.4 \mathrm{MHz}, \mathrm{M}=2, \mathrm{~L}=2 \text {, } \\ & \mathrm{N}=16, \mathrm{~S}=1 \end{aligned}$ |
|  |  |  | 364.18 |  | ns |  |
| $\begin{aligned} & \text { JESD204B DATA INPUT } \\ & \text { TIMING } \end{aligned}$ |  |  |  |  |  | AC-coupled |
| Unit Interval | UI | 81.38 |  | 320 | ps |  |
| Data Rate per Channel (NRZ) |  | 3125 |  | 12288 | Mbps |  |
| Differential Voltage | $V_{\text {DIFF }}$ | 125 |  | 750 | mV |  |
| $V_{\text {TT }}$ Source Impedance | $\mathrm{Z}_{\text {TT }}$ |  | 8.9 | 30 | $\Omega$ |  |
| Differential Impedance | $Z_{\text {RDIFF }}$ | 80 | 105.1 | 120 |  |  |

## ADRV9008-2

| Parameter | Symbol | Min | Typ | Max | Unit | Test Conditions/Comments |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Termination Voltage | $V_{\text {TT }}$ | 1.267 |  |  |  |  |
| AC-Coupled |  |  | 74.45 | 1.33 | V |  |
| Latency | $\mathrm{t}_{\text {LAT_DEFRM }}$ |  |  |  | Clock cycles | Device clock $=245.76 \mathrm{MHz}$, transmitter bandwidth $=200 \mathrm{MHz}$, IQ rate $=491.52 \mathrm{MHz}$, lane rate $=$ 9830.4 MHz, $M=2, L=2, N=16, S=1$ |
|  |  |  | 153.5 |  | ns |  |

[^0]ADRV9008-2

## CURRENT AND POWER CONSUMPTION SPECIFICATIONS

Table 2.


[^1]
## ADRV9008-2

TIMING DIAGRAMS
NOTES

$$
\begin{aligned}
& \mathrm{t}_{\mathrm{H}}=-1.5 \mathrm{~ns} \\
& \mathrm{t}_{\mathrm{S}}=+2.5 \mathrm{~ns}
\end{aligned}
$$

CLK DELAY = 2 ns

$\mathrm{t}^{\prime} \mathrm{H}^{\prime}=+0.5 \mathrm{~ns}$
$\mathrm{t}_{\mathrm{S}}=+0.5 \mathrm{~ns}$

1. $t_{H}$ AND $t_{S}$ ARE THE HOLD AND SETUP TIMES FOR THE REF CLK IN $\pm$ PINS. $\mathrm{t}_{\mathrm{H}}{ }^{\text {AND }} \mathrm{t}^{\prime}$ S REFER TO THE DELAYED HOLD AND SETUP TIMES AT THE DEVICE CORE IN REFERENCE TO THE SYSREF N $\pm$ SIGNALS DELAYED HOLD AND SETUP TIMES AT THE DEVICE CORE IN REFEREN
DUE TO AN INTERNAL BUFFER THAT THE SIGNAL PASSES THROUGH.

Figure 2. SYSREF_IN $\pm$ Setup and Hold Timing


Figure 3. SYSREF_IN $\pm$ Setup and Hold Timing Examples, Relative to Device Clock


Figure 4. Transmitter Attenuation Update via SPI 2 Port

## ABSOLUTE MAXIMUM RATINGS

Table 3.

| Parameter | Rating |
| :--- | :--- |
| VDDA1P3 $^{1}$ to VSSA | -0.3 V to +1.4 V |
| VDDD1P3_DIG to VSSD | -0.3 V to +1.4 V |
| VDD_INTERFACE to VSSA | -0.3 V to +3.0 V |
| VDDA_3P3 to VSSA | -0.3 V to +3.9 V |
| VDDA1P8_TX to VSSA | -0.3 V to +2.0 V |
| VDD_INTERFACE Logic Inputs and | -0.3 V to VDD_ |
| Outputs to VSSD | INTERFACE +0.3 V |
| JESD204B Logic Outputs to VSSA | -0.3 V to VDDA1P3_SER |
| JESD204B Logic Inputs to VSSA | -0.3 V to VDDA1P3_DES |
|  | +0.3 V |
| Input Current to any Pin Except | $\pm 10 \mathrm{~mA}$ |
| $\quad$ Supplies |  |
| Reflow Profile | $260^{\circ} \mathrm{C}$ |
| Maximum Input Power into RF Port | 23 dBm (peak) |
| Maximum Transmitter Voltage | $3: 1$ |
| $\quad$ Standing Wave Ratio (VSWR) |  |
| Maximum Junction Temperature | $110^{\circ} \mathrm{C}$ |
| Storage Temperature Range | $-65^{\circ} \mathrm{C}$ to $+150^{\circ} \mathrm{C}$ |

[^2]Stresses at or above those listed under Absolute Maximum Ratings may cause permanent damage to the product. This is a stress rating only; functional operation of the product at these or any other conditions above those indicated in the operational section of this specification is not implied. Operation beyond the maximum operating conditions for extended periods may affect product reliability.

## REFLOW PROFILE

The ADRV9008-2 reflow profile is in accordance with the JEDEC JESD204B criteria for Pb -free devices. The maximum reflow temperature is $260^{\circ} \mathrm{C}$.

## THERMAL MANAGEMENT

The ADRV9008-2 is a high power device that can dissipate over 3 W depending on the user application and configuration. Because of the power dissipation, the ADRV9008-2 uses an
exposed die package to provide the customer with the most effective method of controlling the die temperature. The exposed die allows cooling of the die directly. Figure 5 shows the profile view of the device mounted to a user printed circuit board (PCB) and a heat sink (typically the aluminum case) to keep the junction (exposed die) below the maximum junction temperature shown in Table 3. The device is designed for a lifetime of 10 years when operating at the maximum junction temperature.

## THERMAL RESISTANCE

Thermal performance is directly linked to PCB design and operating environment. Careful attention to PCB thermal design is required.
$\theta_{\text {IA }}$ is the natural convection junction to ambient thermal resistance measured in a one cubic foot sealed enclosure. $\theta_{\mathrm{JC}}$ is the junction to case thermal resistance.

Thermal resistance data for the ADRV9008-2 mounted on both a JEDEC 2S2P test board and a 10-layer Analog Devices, Inc., evaluation board is listed in Table 4. Do not exceed the absolute maximum junction temperature rating in Table 3. Ten-layer PCB entries refer to the 10-layer Analog Devices evaluation board, which more accurately reflects the PCB used in customer applications.

Table 4. Thermal Resistance ${ }^{1,2}$

| Package Type | $\boldsymbol{\theta}_{\text {JA }}$ | $\boldsymbol{\theta}_{\text {JC_top }}$ | $\boldsymbol{\theta}_{\text {נв }}$ | $\boldsymbol{\Psi}_{\text {Jт }}$ | $\boldsymbol{\Psi}_{\text {JB }}$ | Unit |
| :--- | :--- | :--- | :--- | :--- | :--- | :--- |
| BC-196-13 | 21.1 | 0.04 | 4.9 | 0.3 | 4.9 | ${ }^{\circ} \mathrm{C} / \mathrm{W}$ |

${ }^{1}$ For the $\theta_{\mathrm{Jc}}$ test, $100 \mu \mathrm{~m}$ thermal interface material (TIM) is used. TIM is assumed to have 3.6 thermal conductivity watts/(meter $\times$ Kelvin).
${ }^{2}$ Using enhanced heat removal techniques such as PCB, heat sink, and airflow improves the thermal resistance values.

## ESD CAUTION



ESD (electrostatic discharge) sensitive device.
Charged devices and circuit boards can discharge without detection. Although this product features patented or proprietary protection circuitry, damage may occur on devices subjected to high energy ESD Therefore, proper ESD precautions should be taken to avoid performance degradation or loss of functionality


Figure 5. Typical Thermal Management Solution

PIN CONFIGURATION AND FUNCTION DESCRIPTIONS

|  | 1 | 2 | 3 | 4 | 5 | 6 | 7 | 8 | 9 | 10 | 11 | 12 | 13 | 14 |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| A | VSSA | ORX2_IN+ | ORX2_IN- | VSSA | VSSA | VSSA | VSSA | VSSA | VSSA | VSSA | VSSA | ORX1_IN+ | ORX1_IN- | VSSA |
| B | VDDA1P3 RX_RF | VSSA | VSSA | VSSA | VSSA | VSSA | $\begin{aligned} & \text { RF_EXT- } \\ & \text { LO_I/O- } \end{aligned}$ | $\begin{aligned} & \text { RF_EXT } \\ & \text { LO_I/O } \end{aligned}$ | VSSA | VSSA | VSSA | VSSA | VSSA | VSSA |
| C | GPIO_3p3_0 | GPIO_3p3_3 | VDDA1P3 RX_TX | VSSA | VDDA1P3 RF_VCO_LDO | VDDA1P3 <br> RF_VCO LDO | VDDA1P1 RF_VCO | VDDA1P3 RF_LO | VSSA | VDDA1P3 <br> AUX VCO LDO | VSSA | VDDA_3P3 | GPIO_3p3_9 | RBIAS |
| D | GPIO_3p3_1 | GPIO_3p3_4 | VSSA | VSSA | VSSA | VSSA | VSSA | VSSA | VSSA | VDDA1P1 AUX_VCO | VSSA | VSSA | GPIO_3p3_8 | GPIO_3p3_10 |
| E | GPIO_3p3_2 | GPIO_3p3_5 | GPIO_3p3_6 | VDDA1P8_BB | VDDA1P3 BB | VSSA | REF_CLK_IN+ | REF_CLK_IN- | VSSA | AUX SYNTH OUT | AUXADC_3 | VDDA1P8_TX | GPIO_3p3_7 | GPIO_3p3_11 |
| F | vSSA | VSSA | AUXADC_0 | AUXADC_1 | VSSA | VSSA | VSSA | VSSA | VSSA | VSSA | AUXADC_2 | VSSA | VSSA | VSSA |
| G | VSSA | VSSA | VSSA | VSSA | VDDA1P3 CLOCK SYNTH | VSSA | VDDA1P3 <br> RF_SYNTH | VDDA1P3 AUX SYNTH | $\xrightarrow[\text { RF }]{\text { VYUNTH }}$ | VSSA | VSSA | VSSA | VSSA | VSSA |
| H | TX2_OUT- | VSSA | VSSA | VSSA | VSSA | VSSA | VSSA | VSSA | VSSA | VSSA | GPIO_12 | GPIO_11 | VSSA | TX1_OUT+ |
| J | TX2_OUT+ | VSSA | GPIO_18 | $\overline{\text { RESET }}$ | GP INTERRUPT | TEST | GPIO_2 | GPIO_1 | SDIO | SDO | GPIO_13 | GPIO_10 | VSSA | TX1_OUT- |
| K | vSSA | VSSA | SYSREF_IN+ | SYSREF_IN- | GPIO_5 | GPIO_4 | GPIO_3 | GPIO_0 | SCLK | $\overline{\text { cs }}$ | GPIO_14 | GPIO_9 | VSSA | VSSA |
| L | VSSA | VSSA | $\overline{\text { SYNCIN1- }}$ | SYNCIN1+ | GPIO_6 | GPIO_7 | VSSD | $\begin{gathered} \text { VDDD1P3 } \\ \text { DIG } \end{gathered}$ | $\begin{gathered} \text { VDDD1P3 } \\ \text { DIG } \end{gathered}$ | VSSD | GPIO_15 | GPIO_8 | $\overline{\text { SYNCOUT1- }}$ | $\overline{\text { SYNCOUT1+ }}$ |
| M | VDDA1P1 CLOCK VCO | VSSA | $\overline{\text { SYNCINO- }}$ | $\overline{\text { SYNCINO+ }}$ | ORX1 ENABLE | $\begin{gathered} \text { TX1 } \\ \text { ENABLE } \end{gathered}$ | ORX2 ENABLE | $\begin{gathered} \text { TX2 } \\ \text { ENABLE } \end{gathered}$ | VSSA | GPIO_17 | GPIO_16 | VDD INTERFACE | $\overline{\text { SYNCOUTO- }}$ | $\overline{\text { SYNCOUTO+ }}$ |
| N | VDDA1P3 CLOCK VCO LDO | VSSA | SERDOUT3- | SERDOUT3+ | SERDOUT2- | SERDOUT2+ | VSSA | $\begin{aligned} & \text { VDDA1P3 } \\ & \text { SER } \end{aligned}$ | $\begin{aligned} & \text { VDDA1P3 } \\ & \text { DES } \end{aligned}$ | SERDIN1- | SERDIN1+ | SERDIN0- | SERDIN0+ | VSSA |
| P | AUX SYNTH VTUNE | VSSA | VSSA | SERDOUT1- | SERDOUT1+ | SERDOUT0- | SERDOUT0+ | $\begin{aligned} & \text { VDDA1P3 } \\ & \text { SER } \end{aligned}$ | $\begin{aligned} & \text { VDDA1P3 } \\ & \text { DES } \end{aligned}$ | VSSA | SERDIN3- | SERDIN3+ | SERDIN2- | SERDIN2+ |

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Figure 6. Pin Configuration
Table 5. Pin Function Descriptions

| Pin No. | Type | Mnemonic | Description |
| :--- | :--- | :--- | :--- |
| A1, A4 to A11, A14, B2 to B6, B9 | Input | VSSA | Analog Supply Voltage (V.Vs). |
| to B14, C4, C9, C11, D3 to D9, |  |  |  |
| D11, D12, E6, E9, F1, F2, F5 to |  |  |  |
| F10, F12 to F14, G1 to G4, G6, |  |  |  |
| G10 to G14, H2 to H10, H13, |  |  |  |
| J2, J13, K1, K2, K13, K14, L1, |  |  |  |
| L2, M2, M9, N2, N7, N14, P2, |  |  | Differential Input for Observation Receiver 2. When this pin is |
| P3, P10 | unused, connect to GND. |  |  |
| A2 | Input | ORX2_IN+ |  |


| Pin No. | Type | Mnemonic | Description |
| :---: | :---: | :---: | :---: |
| A3 | Input | ORX2_IN- | Differential Input for Observation Receiver 2. When this pin is unused, connect to GND. |
| A12 | Input | ORX1_IN+ | Differential Input for Observation Receiver 1. When this pin is unused, connect to GND. |
| A13 | Input | ORX1_IN- | Differential Input for Observation Receiver 1. When this pin is unused, connect to GND. |
| B1 | Input | VDDA1P3_RX_RF | Observation Receiver Supply. |
| B7 | Input | RF_EXT_LO_I/O- | Differential External LO Input/Output. If this pin is used for the external LO, the input frequency must be $2 \times$ the desired carrier frequency. When this pin is unused, do not connect. |
| B8 | Input | RF_EXT_LO_I/O+ | Differential External LO Input/Output. If this pin is used for the external LO, the input frequency must be $2 \times$ the desired carrier frequency. When this pin is unused, do not connect. |
| C1 | Input/ output | GPIO_3p3_0 | General-Purpose Inputs and Outputs (GPIO) Pin Referenced to 3.3 V Supply. The alternative function is Auxiliary DAC 4. Because this pin contains an input stage, control the voltage on the pin. When unused, this pin can be tied to ground through a resistor to safeguard against misconfiguration, or this pin can be left floating, programmed as an output, and driven low. |
| C2 | Input/ output | GPIO_3p3_3 | General-Purpose Inputs and Outputs Pin Referenced to 3.3 V Supply. Because this pin contains an input stage, control the voltage on the pin. When unused, this pin can be tied to ground through a resistor to safeguard against misconfiguration, or this pin can be left floating, programmed as an output, and driven low. |
| C3 | Input | VDDA1P3_RX_TX | 1.3 V Supply for Transmitter/Observation Receiver Baseband Circuits. This pin can power the transimpedance amplifier/transmitter (TIA/TX), transconductance/baseband (GM/BB) filter/auxiliary DACs circuits. |
| C5, C6 | Input | VDDA1P3_RF_VCO_LDO | RF VCO LDO Supply Inputs. Connect Pin C5 to Pin C6. Use a separate trace on the PCB back to a common supply point. |
| C7 | Input | VDDA1P1_RF_VCO | 1.1 V VCO Supply. Decouple this pin with a $1 \mu \mathrm{~F}$ capacitor. |
| C8 | Input | VDDA1P3_RF_LO | 1.3 V LO Generator for RF Synthesizer. This pin is sensitive to supply noise. |
| C10 | Input | VDDA1P3_AUX_VCO_LDO | 1.3 V Supply. |
| C12 | Input | VDDA_3P3 | General-Purpose Output Pull-Up Voltage and Auxiliary DAC Supply Voltage. |
| C13 | Input/ output | GPIO_3p3_9 | General-Purpose Inputs and Outputs Pin Referenced to 3.3 V Supply. The alternative function is Auxiliary DAC 9. Because this pin contains an input stage, control the voltage on the pin. When unused, this pin can be tied to ground through a resistor to safeguard against misconfiguration, or this pin can be left floating, programmed as an output, and driven low. |
| C14 | Input/ output | RBIAS | Bias Resistor. Tie this pin to ground using a $14.3 \mathrm{k} \Omega$ resistor. This pin generates an internal current based on an external 1\% resistor. |
| D1 | Input/ output | GPIO_3p3_1 | General-Purpose Inputs and Outputs Pin Referenced to 3.3 V Supply. The alternative function is Auxiliary DAC 5. Because this pin contains an input stage, control the voltage on the pin. When unused, this pin can be tied to ground through a resistor to safeguard against misconfiguration, or this pin can be left floating, programmed as an output, and driven low. |
| D2 | Input/ output | GPIO_3p3_4 | General-Purpose Inputs and Outputs Pin Referenced to 3.3 V Supply. The alternative function is Auxiliary DAC 6. Because this pin contains an input stage, control the voltage on the pin. When unused, this pin can be tied to ground through a resistor to safeguard against misconfiguration, or this pin can be left floating, programmed as an output, and driven low. |
| D10 | Input | VDDA1P1_AUX_VCO | 1.1 V VCO Supply. Decouple this pin with a $1 \mu \mathrm{~F}$ capacitor. |


| Pin No. | Type | Mnemonic | Description |
| :---: | :---: | :---: | :---: |
| D13 | Input/ output | GPIO_3p3_8 | General-Purpose Inputs and Outputs Pin Referenced to 3.3 V Supply. The alternative function is Auxiliary DAC 1. Because this pin contains an input stage, control the voltage on the pin. When unused, this pin can be tied to ground through a resistor to safeguard against misconfiguration, or this pin can be left floating, programmed as an output, and driven low. |
| D14 | Input/ output | GPIO_3p3_10 | General-Purpose Inputs and Outputs Pin Referenced to 3.3 V Supply. The alternative function is Auxiliary DAC 0 . Because this pin contains an input stage, control the voltage on the pin. When unused, this pin can be tied to ground through a resistor to safeguard against misconfiguration, or this pin can be left floating, programmed as an output, and driven low. |
| E1 | Input/ output | GPIO_3p3_2 | General-Purpose Inputs and Outputs Pin Referenced to 3.3 V Supply. Because this pin contains an input stage, control the voltage on the pin. When unused, this pin can be tied to ground through a resistor to safeguard against misconfiguration, or this pin can be left floating, programmed as an output, and driven low. |
| E2 | Input/ output | GPIO_3p3_5 | General-Purpose Inputs and Outputs Pin Referenced to 3.3 V Supply. The alternative function is Auxiliary DAC 7. Because this pin contains an input stage, control the voltage on the pin. When unused, this pin can be tied to ground through a resistor to safeguard against misconfiguration, or this pin can be left floating, programmed as an output, and driven low. |
| E3 | Input/ output | GPIO_3p3_6 | General-Purpose Inputs and Outputs Pin Referenced to 3.3 V Supply. The alternative function is Auxiliary DAC 8. Because this pin contains an input stage, control the voltage on the pin. When unused, this pin can be tied to ground through a resistor to safeguard against misconfiguration, or this pin can be left floating, programmed as outputs, and driven low. |
| E4 | Input | VDDA1P8_BB | 1.8 V Supply for the ADC and DAC. |
| E5 | Input | VDDA1P3_BB | 1.3 V Supply for the ADC, DAC, and auxiliary ADC. |
| E7 | Input | REF_CLK_IN+ | Device Clock Differential Input. |
| E8 | Input | REF_CLK_IN- | Device Clock Differential Input Negative. |
| E10 | Output | AUX_SYNTH_OUT | Auxiliary PLL Output. When this pin is unused, do not connect. |
| E11, F3, F4, F11 | Input | AUXADC_0 through AUXADC_3 | Auxiliary ADC Inputs. When these pins are unused, connect these pins to GND with a pull-down resistor or connect these pins directly to GND. |
| E12 | Input | VDDA1P8_TX | 1.8 V Supply for Transmitter. |
| E13 | Input/ output | GPIO_3p3_7 | General-Purpose Inputs and Outputs Pin Referenced to 3.3 V Supply. The alternative function is Auxiliary DAC 2. Because this pin contains an input stage, control the voltage on the pin. When unused, this pin can be tied to ground through a resistor to safeguard against misconfiguration, or this pin can be left floating, programmed as an output, and driven low. |
| E14 | Input/ output | GPIO_3p3_11 | General-Purpose Inputs and Outputs Pin Referenced to 3.3 V Supply. The alternative function is Auxiliary DAC 3. Because this pin contains an input stage, control the voltage on the pin. When unused, this pin can be tied to ground through a resistor to safeguard against misconfiguration, or this pin can be left floating, programmed as an output, and driven low. |
| G5 | Input | VDDA1P3_CLOCK_SYNTH | 1.3 V Supply Input for Clock Synthesizer. Use a separate trace on the PCB back to a common supply point. |
| G7 | Input | VDDA1P3_RF_SYNTH | 1.3 V RF Synthesizer Supply Input. This pin is sensitive to aggressors. |
| G8 | Input | VDDA1P3_AUX_SYNTH | 1.3 V Auxiliary Synthesizer Supply Input. |
| G9 | Output | RF_SYNTH_VTUNE | RF Synthesizer PLL Tuning Voltage ( $\mathrm{V}_{\text {TUNE }}$ ) Output. |


| Pin No. | Type | Mnemonic | Description |
| :---: | :---: | :---: | :---: |
| H1 | Output | TX2_OUT- | Transmitter 2 Negative Output. When unused, do not connect this pin. |
| H11 | Input/ output | GPIO_12 | Digital GPIO, 1.8 V to 2.5 V . Because this pin contains an input stage, control the voltage on the pin. When unused, this pin can be tied to ground through a resistor to safeguard against misconfiguration, or the pin can be left floating, programmed as an output, and driven low. |
| H12 | Input/ output | GPIO_11 | Digital GPIO, 1.8 V to 2.5 V . Because this pin contains an input stage, control the voltage on the pin. When unused, this pin can be tied to ground through a resistor to safeguard against misconfiguration, or the pin can be left floating, programmed as an output, and driven low. |
| H14 | Output | TX1_OUT+ | Transmitter 1 Positive Output. When unused, do not connect this pin. |
| J1 | Output | TX2_OUT+ | Transmitter 2 Positive Output. When unused, do not connect this pin. |
| J3 | Input/ output | GPIO_18 | Digital GPIO, 1.8 V to 2.5 V . The joint test action group (JTAG) function is test clock (TCLK). Because this pin contains an input stage, control the voltage on the pin. When unused, this pin can be tied to ground through a resistor to safeguard against misconfiguration, or the pin can be left floating, programmed as an output, and driven low. |
| J4 | Input | $\overline{\text { RESET }}$ | Active Low Chip Reset. |
| J5 | Output | GP_INTERRUPT | General-Purpose Digital Interrupt Output Signal. When unused, do not connect this pin. |
| J6 | Input | TEST | Pin Used for JTAG Boundary Scan. When unused, connect this pin to GND. |
| J7 | Input/ output | GPIO_2 | Digital GPIO, 1.8 V to 2.5 V . The user sets the JTAG function to 0. Because this pin contains an input stage, control the voltage on the pin. When unused, this pin can be tied to ground through a resistor to safeguard against misconfiguration, or the pin can be left floating, programmed as an output, and driven low. |
| J8 | Input/ output | GPIO_1 | Digital GPIO, 1.8 V to 2.5 V . The user sets the JTAG function to 0. Because this pin contains an input stage, control the voltage on the pin. When unused, this pin can be tied to ground through a resistor to safeguard against misconfiguration, or the pin can be left floating, programmed as an output, and driven low. |
| J9 | Input/ output | SDIO | Serial Data Input in 4-Wire Mode or Input/Output in 3-Wire Mode. |
| J10 | Output | SDO | Serial Data Output. In SPI 3-wire mode, do not connect this pin. |
| J11 | Input/ output | GPIO_13 | Digital GPIO, 1.8 V to 2.5 V . Because this pin contains an input stage, control the voltage on the pin. When unused, this pin can be tied to ground through a resistor to safeguard against misconfiguration, or the pin can be left floating, programmed as an output, and driven low. |
| J12 | Input/ output | GPIO_10 | Digital GPIO, 1.8 V to 2.5 V . Because this pin contains an input stage, control the voltage on the pin. When unused, this pin can be tied to ground through a resistor to safeguard against misconfiguration, or the pin can be left floating, programmed as an output, and driven low. |
| J14 | Output | TX1_OUT- | Transmitter 1 Negative Output. When unused, do not connect this pin. |
| K3 | Input | SYSREF_IN+ | LVDS Positive Input. |
| K4 | Input | SYSREF_IN- | LVDS Negative Input. |
| K5 | Input/ output | GPIO_5 | Digital GPIO, 1.8 V to 2.5 V . The JTAG function is test data output (TDO). Because this pin contains an input stage, control the voltage on the pin. When unused, this pin can be tied to ground through a resistor to safeguard against misconfiguration, or the pin can be left floating, programmed as an output, and driven low. |


| Pin No. | Type | Mnemonic | Description |
| :---: | :---: | :---: | :---: |
| K6 | Input/ output | GPIO_4 | Digital GPIO, 1.8 V to 2.5 V . The JTAG function is test rest ( $\overline{\overline{\text { TRST }}) .}$ Because this pin contains an input stage, control the voltage on the pin. When unused, this pin can be tied to ground through a resistor to safeguard against misconfiguration, or the pin can be left floating, programmed as an output, and driven low. |
| K7 | Input/ output | GPIO_3 | Digital GPIO, 1.8 V to 2.5 V . The user sets the JTAG function to 1 . Because this pin contains an input stage, control the voltage on the pin. When unused, this pin can be tied to ground through a resistor to safeguard against misconfiguration, or the pin can be left floating, programmed as an output, and driven low. |
| K8 | Input/ output | GPIO_0 | Digital GPIO, 1.8 V to 2.5 V . The user sets the JTAG function to 1 . Because this pin contains an input stage, control the voltage on the pin. When unused, this pin can be tied to ground through a resistor to safeguard against misconfiguration, or the pin can be left floating, programmed as an output, and driven low. |
| K9 | Input | SCLK | Serial Data Bus Clock. |
| K10 | Input | $\overline{\mathrm{CS}}$ | Serial Data Bus Chip Select, Active Low. |
| K11 | Input/ output | GPIO_14 | Digital GPIO, 1.8 V to 2.5 V . Because this pin contains an input stage, control the voltage on the pin. When unused, this pin can be tied to ground through a resistor to safeguard against misconfiguration, or the pin can be left floating, programmed as an output, and driven low. |
| K12 | Input/ output | GPIO_9 | Digital GPIO, 1.8 V to 2.5 V . Because this pin contains an input stage, control the voltage on the pin. When unused, this pin can be tied to ground through a resistor to safeguard against misconfiguration, or the pin can be left floating, programmed as an output, and driven low. |
| L3 | Input | $\overline{\text { SYNCIN1- }}$ | LVDS Negative Input. When unused, connect this pin to GND with a pull-down resistor or connect this pin directly to GND. |
| L4 | Input | $\overline{\text { SYNCIN1+ }}$ | LVDS Positive Input. When unused, connect this pin to GND with a pull-down resistor or connect this pin directly to GND. |
| L5 | Input/ output | GPIO_6 | Digital GPIO, 1.8 V to 2.5 V . The JTAG function is test data input (TDI). Because this pin contains an input stage, control the voltage on the pin. When unused, this pin can be tied to ground through a resistor to safeguard against misconfiguration, or the pin can be left floating, programmed as an output, and driven low. |
| L6 | Input/ output | GPIO_7 | Digital GPIO, 1.8 V to 2.5 V . The JTAG function is test mode select input (TMS). Because this pin contains an input stage, control the voltage on the pin. When unused, this pin can be tied to ground through a resistor to safeguard against misconfiguration, or the pin can be left floating, programmed as an output, and driven low. |
| L7, L10 | Input | VSSD | Digital Supplies. |
| L8, L9 | Input | VDDD1P3_DIG | 1.3 V Digital Core. Connect L8 and L9 with a separate trace to common supply point. |
| L11 | Input/ output | GPIO_15 | Digital GPIO, 1.8 V to 2.5 V . Because this pin contains an input stage, control the voltage on the pin. When unused, this pin can be tied to ground through a resistor to safeguard against misconfiguration, or the pin can be left floating, programmed as an output, and driven low. |
| L12 | Input/ output | GPIO_8 | Digital GPIO, 1.8 V to 2.5 V . Because this pin contains an input stage, control the voltage on the pin. When unused, this pin can be tied to ground through a resistor to safeguard against misconfiguration, or the pin can be left floating, programmed as an output, and driven low. |
| L13 | Output | $\overline{\text { SYNCOUT1- }}$ | LVDS Negative Output. When unused, do not connect this pin. |
| L14 | Output | $\overline{\text { SYNCOUT1+ }}$ | LVDS Positive Output. When unused, do not connect this pin. |
| M1 | Input | VDDA1P1_CLOCK_VCO | 1.1 VVCO Supply. Decouple this pin with a $1 \mu \mathrm{~F}$ capacitor. |


| Pin No. | Type | Mnemonic | Description |
| :--- | :--- | :--- | :--- |
| M3 | Input | SYNCIN0- | JESD204B Receiver Channel 0 Data Link LVDS Input. This pin <br> forms the sync signal associated with observation receiver channel <br> data on the JESD204B interface. When unused, connect this |
| M4 |  |  | pin to GND with a pull-down resistor or directly to GND. <br> JESD204B Receiver Channel 0 Data Link LVDS Input. This pin <br> forms the sync signal associated with observation receiver channel <br> data on the JESD204B interface. When unused, connect this |
| M5 |  | SYNCIN0+ |  |
| Min to GND with a pull-down resistor or connect this pin |  |  |  |
| directly to GND. |  |  |  |

## ADRV9008-2

| Pin No. | Type | Mnemonic | Description |
| :--- | :--- | :--- | :--- |
| P4 | Output | SERDOUT1- | RF CML Differential Negative Output 1. When unused, do not <br> connect this pin. <br> RF CML Differential Positive Output 1. When unused, do not |
| P5 | Output | SERDOUT1+ | Connect this pin. <br> RF CML Differential Negative Output 0. When unused, do not <br> connect this pin. |
| P6 | Output | SERDOUT0- | RF CML Differential Positive Output 0. When unused, do not <br> connect this pin. |
| P7 | Output | SERDOUT0+ | RF CML Differential Negative Input 3. When unused, do not <br> connect this pin. |
| P11 | Input | SERDIN3- | RF CML Differential Positive Input 3. When unused, do not <br> connect this pin. |
| P12 | Input | SERDIN3+ | RF CML Differential Negative Input 2. When unused, do not <br> Connect this pin. |
| P13 | Input | SERDIN2- | RML Differential Positive Input 2. When unused, do not |
| Connect this pin. |  |  |  |

## TYPICAL PERFORMANCE CHARACTERISTICS

The temperature settings refer to the die temperature.

75 MHz TO 525 MHz BAND


Figure 7. Transmitter Continuous Wave (CW) Output Power vs. Transmitter LO Frequency, Transmitter QEC and External LO Leakage Active, Transmitter $50 \mathrm{MHz} / 100 \mathrm{MHz}$ Bandwidth Mode, IQ Rate $=122.88 \mathrm{MHz}$, Attenuation $=0 \mathrm{~dB}$, Not De-Embedded


Figure 8. Transmitter Image Rejection vs. Baseband Offset Frequency and Transmitter Attenuation, QEC Trained with Three Tones Placed at 10 MHz , 48 MHz , and 100 MHz (Tracking On), Total Combined Power $=-10 \mathrm{dBFS}$, Correction Then Frozen (Tracking Turned Off), CW Tone Swept Across Large Signal Bandwidth, $L O=75.2 \mathrm{MHz}$


Figure 9. Transmitter Image Rejection vs. Baseband Offset Frequency and Transmitter Attenuation, QEC Trained with Three Tones Placed at 10 MHz , 48 MHz , and 100 MHz (Tracking On), Total Combined Power $=-10 \mathrm{dBFS}$, Correction Then Frozen (Tracking Turned Off), CW Tone Swept Across Large Signal Bandwidth, $\mathrm{LO}=300 \mathrm{MHz}$


Figure 10. Transmitter Image Rejection vs. Baseband Offset Frequency and Transmitter Attenuation, QEC Trained with Three Tones Placed at 10 MHz , 48 MHz , and 100 MHz (Tracking On), Total Combined Power $=-10 \mathrm{dBFS}$, Correction Then Frozen (Tracking Turned Off), CW Tone Swept Across Large Signal Bandwidth, $\mathrm{LO}=525 \mathrm{MHz}$


Figure 11. Transmitter Pass Band Flatness vs. Baseband Offset Frequency, Off Chip Match Response De-Embedded, $L O=300 \mathrm{MHz}$, Calibrated at $25^{\circ} \mathrm{C}$


Figure 12. Transmitter LO Leakage vs. Transmitter LO Frequency, Transmitter Attenuation $=0$ dB, Baseband Tone Frequency $=10 \mathrm{MHz}$, Tracked


Figure 13. Transmitter to Transmitter Isolation vs. Transmitter LO Frequency, Temperature $=25^{\circ} \mathrm{C}$


Figure 14. Transmitter Noise vs. Transmitter Attenuator Setting, Offset $=50 \mathrm{MHz}$


Figure 15. Transmitter Adjacent Channel Leakage Ratio vs. Transmitter Attenuator Setting, Signal Offset $=0 \mathrm{MHz}, L O=75 \mathrm{MHz}, L T E=20 \mathrm{MHz}$, Peak to Average Ratio $(P A R)=12$ dB, DAC Boost Normal, Upper Side and Lower Side, Performance Limited by Spectrum Analyzer at Higher Attenuation Settings


Figure 16. Transmitter Adjacent Channel Leakage Ratio vs. Transmitter Attenuator Setting, Signal Offset $=0 \mathrm{MHz}, L O=300 \mathrm{MHz}, L T E=20 \mathrm{MHz}, P A R=$ 12 dB, DAC Boost Normal, Upper Side and Lower Side, Performance Limited by Spectrum Analyzer at Higher Attenuation Settings


Figure 17. Transmitter Adjacent Channel Leakage Ratio vs. Transmitter Attenuator Setting, Signal Offset $=0 \mathrm{MHz}, L O=525 \mathrm{MHz}, L T E=20 \mathrm{MHz}, P A R=$ 12 dB, DAC Boost Normal, Upper Side and Lower Side, Performance Limited by Spectrum Analyzer at Higher Attenuation Settings


Figure 18. Transmitter OIP3 Right vs. Transmitter Attenuator Setting, LO $=75 \mathrm{MHz}$, Total Root Mean Square (RMS) Power $=-12 \mathrm{dBFS}, 20 \mathrm{MHz} / 25 \mathrm{MHz}$ Tones


Figure 19. Transmitter OIP3 Right vs. Transmitter Attenuator Setting, $L O=$ 300 MHz , Total RMS Power $=-12 \mathrm{dBFS}, 20 \mathrm{MHz} / 25 \mathrm{MHz}$ Tones


Figure 20. Transmitter OIP3 Right vs. Transmitter Attenuator Setting, LO = 525 MHz , Total RMS Power $=-12 \mathrm{dBFS}, 20 \mathrm{MHz} / 25 \mathrm{MHz}$ Tones


Figure 21. Transmitter OIP3 Right vs. Baseband Tone Pair Swept Across Pass Band, $L O=75 \mathrm{MHz}$, Total RMS Power $=-12 \mathrm{dBFS}$, Transmitter Attenuation $=4 \mathrm{~dB}$


Figure 22. Transmitter OIP3 Right vs. Baseband Frequency Offset, $\mathrm{LO}=$ 300 MHz , Total RMS Power $=-12 \mathrm{dBFS}$, Transmitter Attenuation $=4 \mathrm{~dB}$


Figure 23. Transmitter OIP3 Right vs. Baseband Frequency Offset, LO = 525 MHz , Total RMS Power $=-12 \mathrm{dBFS}$, Transmitter Attenuation $=4 \mathrm{~dB}$


Figure 24. Transmitter HD2 vs. Transmitter Attenuator Setting, Baseband Frequency $=10 \mathrm{MHz}, L O=75 \mathrm{MHz}, C W=-15 \mathrm{dBFS}$


Figure 25. Transmitter HD2 vs. Transmitter Attenuator Setting, Baseband Frequency $=10 \mathrm{MHz}, L O=300 \mathrm{MHz}, C W=-15 \mathrm{dBFS}$


Figure 26. Transmitter HD2 vs. Transmitter Attenuator Setting, Baseband Frequency $=10 \mathrm{MHz}, L O=525 \mathrm{MHz}, C W=-15 \mathrm{dBFS}$


Figure 27. Transmitter HD3 vs. Transmitter Attenuator Setting, $L O=75 \mathrm{MHz}$, $C W=-15 \mathrm{dBFS}$, Baseband Frequency $=10 \mathrm{MHz}$


Figure 28. Transmitter HD3 vs. Transmitter Attenuator Setting, LO = $300 \mathrm{MHz}, \mathrm{CW}=-15 \mathrm{dBFS}$, Baseband Frequency $=10 \mathrm{MHz}$


Figure 29. Transmitter HD3 vs. Transmitter Attenuator Setting, LO = $525 \mathrm{MHz}, \mathrm{CW}=-15 \mathrm{dBFS}$, Baseband Frequency $=10 \mathrm{MHz}$


Figure 30. Transmitter HD3 Image Appears on Same Side as Desired Signal vs. Transmitter Attenuator Setting, $L O=75 \mathrm{MHz}, C W=-15 \mathrm{dBFS}$


Figure 31. Transmitter HD3 Image Appears on Same Side as Desired Signal vs. Transmitter Attenuator Setting, $L O=300 \mathrm{MHz}, C W=-15 \mathrm{dBFS}$


Figure 32. Transmitter HD3 Image Appears on Same Side as Desired Signal vs. Transmitter Attenuator Setting, LO $=525 \mathrm{MHz}, C W=-15 \mathrm{dBFS}$


Figure 33. Transmitter Attenuator Step Error vs. Transmitter Attenuator Setting, $L O=75 \mathrm{MHz}$, Baseband Frequency $=10 \mathrm{MHz}$, Backoff $=15 \mathrm{dBFS}$


Figure 34. Transmitter Attenuator Step Error vs. Transmitter Attenuator Setting, LO = 300 MHz , Baseband Frequency $=10 \mathrm{MHz}$, Backoff $=15 \mathrm{dBFS}$


Figure 35. Transmitter Attenuator Step Error vs. Transmitter Attenuator Setting, $L O=525 \mathrm{MHz}$, Baseband Frequency $=10 \mathrm{MHz}$, Backoff $=15 \mathrm{dBFS}$


Figure 36. Transmitter EVM vs. Transmitter Attenuation, LTE $=20 \mathrm{MHz}$, Signal Centered on DC, $L O=75 \mathrm{MHz}$


Figure 37. Transmitter EVM vs. Transmitter Attenuation, LTE $=20 \mathrm{MHz}$, Signal Centered on DC, LO $=300 \mathrm{MHz}$


Figure 38. Transmitter EVM vs. Transmitter Attenuation, $L T E=20 \mathrm{MHz}$, Signal Centered on DC, LO $=525 \mathrm{MHz}$


Figure 39. Observation Receiver LO Leakage vs. LO Frequency, 75 MHz , 300 MHz , and 525 MHz , Attenuation $=0 \mathrm{~dB}$


Figure 40. Observation Receiver Noise Figure vs. Observation Receiver Attenuator Setting, LO = 75 MHz , Total Nyquist Integration Bandwidth


Figure 41. Observation Receiver Noise Figure vs. Observation Receiver Attenuator Setting, LO = 300 MHz , Total Nyquist Integration Bandwidth


Figure 42. Observation Receiver Noise Figure vs. Observation Receiver Attenuator Setting, LO $=525 \mathrm{MHz}$, Total Nyquist Integration Bandwidth


Figure 43. Observation Receiver IIP2, Sum and Difference Products vs.f1 Offset Frequency, Tones Separated by 1 MHz Swept Across Pass Band at -25 dBm Each, $L O=75 \mathrm{MHz}$, Attenuation $=0 \mathrm{~dB}$


Figure 44. Observation Receiver IIP2, Sum and Difference Products vs. f1 Offset Frequency, Tones Separated by 1 MHz Swept Across Pass Band at -25 dBm Each, $L O=300 \mathrm{MHz}$, Attenuation $=0 \mathrm{~dB}$


Figure 45. Observation Receiver IIP2, Sum and Difference Products vs. f1 Offset Frequency, Tones Separated by 1 MHz Swept Across Pass Band at -25 dBm Each, LO $=525 \mathrm{MHz}$, Attenuation $=0 \mathrm{~dB}$


Figure 46. Observation Receiver IIP2, Sum and Difference Products vs. Observation Receiver Attenuation, $L O=75 \mathrm{MHz}$, Tone $1=95 \mathrm{MHz}$, Tone $2=96 \mathrm{MHz}$ at
-25 dBm Plus Attenuation


Figure 47. Observation Receiver IIP2, Sum and Difference Products vs. Observation Receiver Attenuation, $L O=300 \mathrm{MHz}$, Tone $1=320 \mathrm{MHz}$, Tone $2=321 \mathrm{MHz}$ at -25 dBm Plus Attenuation


Figure 48. Observation Receiver IIP2, Sum and Difference Products vs. Observation Receiver Attenuation, $\mathrm{LO}=525 \mathrm{MHz}$, Tone $1=545 \mathrm{MHz}$, Tone $2=546 \mathrm{MHz}$ at -25 dBm Plus Attenuation


Figure 49. Observation Receiver IIP2, f1 - f2 vs. Intermodulation Frequency, $L O=75 \mathrm{MHz}$, Tone $1=77 \mathrm{MHz}$, Tone $2=$ Swept, -25 dBm Each, Attenuation $=0 d B$ Change


Figure 50. Observation Receiver IIP2,f1 - f2 vs. Intermodulation Frequency, $L O=300 \mathrm{MHz}$, Tone $1=302 \mathrm{MHz}$, Tone $2=$ Swept, -25 dBm Each, Attenuation $=0 d B$


Figure 51. Observation Receiver IIP2, f1 - f2 vs. Intermodulation Frequency, LO = 525 MHz , Tone $1=527 \mathrm{MHz}$, Tone $2=$ Swept, -25 dBm Each, Attenuation $=0 \mathrm{~dB}$


Figure 52. Observation Receiver IIP2, f1 - f2 vs. Observation Receiver Attenuation, $L O=75 \mathrm{MHz}$, Tone $1=77 \mathrm{MHz}$, Tone $2=97 \mathrm{MHz}$ at -25 dBm Plus Attenuation


Figure 53. Observation Receiver IIP2,f1 - f2 vs. Observation Receiver Attenuation, $\mathrm{LO}=300 \mathrm{MHz}$, Tone $1=302 \mathrm{MHz}$, Tone $2=322 \mathrm{MHz}$ at -25 dBm Plus Attenuation


Figure 54. Observation Receiver IIP2, f1 - f2 vs. Observation Receiver Attenuation, $L O=525 \mathrm{MHz}$, Tone $1=527 \mathrm{MHz}$, Tone $2=547 \mathrm{MHz}$ at -25 dBm Plus Attenuation


Figure 55. Observation Receiver IIP3, $2 f 1$ - f2 vs. Intermodulation Frequency, LO $=75 \mathrm{MHz}$, Attenuation $=0 \mathrm{~dB}$, Tones Separated by 1 MHz Swept Across Pass Band at -25 dBm Each


Figure 56. Observation Receiver IIP3, $2 f 1$ - f2 vs. f1 Offset Frequency, $L O=$ 300 MHz , Attenuation $=0 \mathrm{~dB}$, Tones Separated by 1 MHz Swept Across Pass Band at -25 dBm Each


Figure 57. Observation Receiver IIP3, $2 f 1$ - f2 vs. Observation Receiver Attenuation, $\mathrm{LO}=75 \mathrm{MHz}$, Tone $1=100 \mathrm{MHz}$, Tone $2=101 \mathrm{MHz}$ at -24 dBm Plus Attenuation


Figure 58. Observation Receiver IIP3, 2f1-f2 vs. Attenuation, LO = 300 MHz , Tone $1=345 \mathrm{MHz}$, Tone $2=346 \mathrm{MHz}$ at -24 dBm Plus Attenuation


Figure 59. Observation Receiver IIP3, $2 f 1$ - f2 vs. Swept Pass Band Frequency, $L O=300 \mathrm{MHz}$, Attenuation $=0 \mathrm{~dB}$, Tone $1=302 \mathrm{MHz}$, Tone $2=$ Swept Across the Pass Band, Tones Separated by 1 MHz Swept Across Pass Band at
-19 dBm Each


Figure 60. Observation Receiver IIP3, $2 f 1$-f2 vs. Observation Receiver Attenuation, $\mathrm{LO}=300 \mathrm{MHz}$, Tone $1=302 \mathrm{MHz}$, Tone $2=352 \mathrm{MHz}$ at -19 dBm Plus Attenuation


Figure 61. Observation Receiver Image Rejection vs. Baseband Frequency Offset and Attenuation, CW Signal Swept Across the Band, $L O=75 \mathrm{MHz}$


Figure 62. Observation Receiver Image Rejection vs. Baseband Frequency Offset and Attenuation, CW Signal Swept Across the Band, $L O=300 \mathrm{MHz}$


Figure 63. Observation Receiver Gain vs. Observation Receiver Attenuation, $L O=75 \mathrm{MHz}$


Figure 64. Observation Receiver Gain vs. Observation Receiver Attenuation, LO $=300 \mathrm{MHz}$


Figure 65. Observation Receiver Gain Step Error vs. Observation Receiver Attenuator, $\mathrm{LO}=75 \mathrm{MHz}$


Figure 66. Observation Receiver Gain Step Error vs. Observation Receiver Attenuator, $\mathrm{LO}=325 \mathrm{MHz}$


Figure 67. Observation Receiver Attenuator Gain Step Error vs. Observation Receiver Attenuator, $\mathrm{LO}=525 \mathrm{MHz}$


Figure 68. Normalized Observation Receiver Baseband Flatness vs. Baseband Offset Frequency, $L O=75 \mathrm{MHz}$, Attenuation $=0 \mathrm{~dB}$


Figure 69. Observation Receiver DC Offset vs. Observation Receiver Attenuation, $\mathrm{LO}=75 \mathrm{MHz}$, Baseband Frequency $=50 \mathrm{MHz}$


Figure 70. Observation Receiver DC Offset vs. Observation Receiver Attenuation, LO $=325 \mathrm{MHz}$, Baseband Frequency $=50 \mathrm{MHz}$


Figure 71. Observation Receiver HD2 vs. Offset Frequency and Attenuation, LO $=75 \mathrm{MHz}$, Tone Level $=-21 \mathrm{dBm}$ Plus Attenuation


Figure 72. Observation Receiver HD2 vs. Offset Frequency and Attenuation, $L O=300 \mathrm{MHz}$, Tone Level $=-22 \mathrm{dBm}$ Plus Attenuation


Figure 73. Observation Receiver HD3 Left and Right vs. Frequency Offset from $L O$, Tone Level $=-21 \mathrm{dBm}$ at Attenuation $=0 \mathrm{~dB}, L O=75 \mathrm{MHz}$


Figure 74. Observation Receiver HD3 Left and Right vs. Frequency Offset from LO, Tone Level $=-22 \mathrm{dBm}$ at Attenuation $=0 \mathrm{~dB}, L O=300 \mathrm{MHz}$


Figure 75. Observation Receiver HD3 Left and Right vs. Frequency Offset from LO, Tone Level - 22 dBm at Attenuation $=0 \mathrm{~dB}, \mathrm{LO}=525 \mathrm{MHz}$


Figure 76. Transmitter to Observation Receiver Isolation vs. LO Frequency, Temperature $=25^{\circ} \mathrm{C}$


Figure 77. LO Phase Noise vs. Frequency Offset, LO $=75 \mathrm{MHz}$, PLL Loop Bandwidth $=50 \mathrm{kHz}$


Figure 78. LO Phase Noise vs. Frequency Offset, $L O=300 \mathrm{MHz}$, PLL Loop Bandwidth $=50 \mathrm{kHz}$


Figure 79. LO Phase Noise vs. Frequency Offset, $L O=525 \mathrm{MHz}$, PLL Loop Bandwidth $=50 \mathrm{kHz}$

## ADRV9008-2

## 650 MHz TO 3000 MHz BAND



Figure 80. Transmitter Matching Circuit Path Loss vs. LO Frequency (Can be Used for De-Embedding Performance Data)


Figure 81. Transmitter CW Output Power vs. Transmitter LO Frequency, Transmitter QEC and External LO Leakage Active, Transmitter in $200 \mathrm{MHz} / 450 \mathrm{MHz}$ Bandwidth Mode, IQ Rate $=491.52 \mathrm{MHz}$, Attenuation = 0 dB (Not De-Embedded)


Figure 82. Transmitter Image Rejection vs. Baseband Frequency Offset and Attenuation, QEC Trained with Three Tones Placed at $10 \mathrm{MHz}, 50 \mathrm{MHz}$, and 100 MHz (Tracking On), Total Combined Power $=-6$ dBFS, Correction Then Frozen (Tracking Turned Off), CW Tone Swept Across Large Signal Bandwidth


Figure 83. Transmitter Pass Band Flatness vs. Baseband Offset Frequency, $L O=2600 \mathrm{MHz}$


Figure 84. Transmitter LO Leakage vs. Transmitter LO Frequency, Transmitter Attenuation $=0 \mathrm{~dB}$


Figure 85. Transmitter to Transmitter Isolation vs. Transmitter LO Frequency, Temperature $=25^{\circ} \mathrm{C}$


Figure 86. Transmitter Noise vs. Transmitter Attenuator Setting


Figure 87. Transmitter Adjacent Channel Leakage Ratio vs. Transmitter Attenuator Setting, Signal Offset $=90 \mathrm{MHz}, L O=650 \mathrm{MHz}, L T E=20 \mathrm{MHz}$, $P A R=12 d B$, Upper Side and Lower Side


Figure 88. Transmitter Adjacent Channel Leakage Ratio vs. Transmitter Attenuator Setting, Signal Offset $=90 \mathrm{MHz}, \mathrm{LO}=1850 \mathrm{MHz}$, $L T E=20 \mathrm{MHz}, P A R=12 \mathrm{~dB}$, Upper Side and Lower Side


Figure 89. Transmitter Adjacent Channel Leakage Ratio vs. Transmitter Attenuator Setting, Signal Offset $=90 \mathrm{MHz}, L O=2850 \mathrm{MHz}, L T E=20 \mathrm{MHz}$, $P A R=12 d B$, Upper Side and Lower Side


Figure 90. Transmitter OIP3, Right or Upper Sideband Response vs. Transmitter Attenuator Setting, LO = 850 MHz , Digital Backoffper Tone = 15 dB


Figure 91. Transmitter OIP3 Right vs. Transmitter Attenuator Setting, LO = 1850 MHz , Digital Backoffper Tone $=15 \mathrm{~dB}$


Figure 92. Transmitter OIP3 Right vs. Transmitter Attenuator Setting, $\mathrm{LO}=$ 2650 MHz , Digital Backoffper Tone $=15 \mathrm{~dB}$


Figure 93. Transmitter OIP3 Right vs. Baseband Tone Pair Swept Across Pass Band, LO $=850 \mathrm{MHz}$, Digital Backoff per Tone $=15 \mathrm{~dB}$


Figure 94. Transmitter OIP3 Right vs. Baseband Tone Pair Swept Across Pass Band, $L O=1850 \mathrm{MHz}$, Digital Backoff per Tone $=15 \mathrm{~dB}$


Figure 95. Transmitter OIP3 Right vs. Baseband Tone Pair Swept Across Pass Band, $L O=2850 \mathrm{MHz}$, Digital Backoff per Tone $=15 \mathrm{~dB}$


Figure 96. Transmitter HD2 vs. Transmitter Attenuator Setting, Baseband Frequency $=10 \mathrm{MHz}, L O=1850 \mathrm{MHz}$, Digital Backoff $=15 \mathrm{~dB}$


Figure 97. Transmitter HD3 vs. Transmitter Attenuator Setting, LO $=650 \mathrm{MHz}$, Digital Backoff $=15 \mathrm{~dB}$


Figure 98. Transmitter HD3 vs. Transmitter Attenuator Setting, $L O=1850 \mathrm{MHz}$, Digital Backoff $=15 \mathrm{~dB}$,


Figure 99. Transmitter HD3 vs. Transmitter Attenuation Setting, $L O=2850 \mathrm{MHz}$, Digital Backoff $=15 \mathrm{~dB}$


Figure 100. Transmitter HD3 Image Appears on Same Side as Desired Signal vs. Transmitter Attenuation Setting, LO = 1850 MHz ,

Digital Backoff $=15 \mathrm{~dB}$


Figure 101. Transmitter Attenuator Step Error vs. Transmitter Attenuator Setting, LO = 650 MHz


Figure 102. Transmitter Output Spurious, Transmitter $1=650 \mathrm{MHz}$, $L T E=5 \mathrm{MHz}$, Offset $=10 \mathrm{MHz}, R M S=-12 \mathrm{dBFS}$, Temperature $=25^{\circ} \mathrm{C}$


Figure 103. Transmitter Output Spurious, Transmitter $2=650 \mathrm{MHz}$, $L T E=5 \mathrm{MHz}$, Offset $=10 \mathrm{MHz}, R M S=-12 \mathrm{dBFS}$, Temperature $=25^{\circ} \mathrm{C}$


Figure 104. Transmitter Output Spurious, Transmitter $1=1850 \mathrm{MHz}$, $L T E=5 \mathrm{MHz}$, Offset $=10 \mathrm{MHz}$, RMS $=-12 \mathrm{dBFS}$, Temperature $=25^{\circ} \mathrm{C}$


Figure 105. Transmitter Output Spurious, Transmitter $2=1850 \mathrm{MHz}$, $L T E=5 \mathrm{MHz}$, Offset $=10 \mathrm{MHz}$, RMS $=-12 \mathrm{dBFS}$, Temperature $=25^{\circ} \mathrm{C}$


Figure 106. Transmitter Output Spurious, Transmitter $1=2850 \mathrm{MHz}$, $L T E=5 \mathrm{MHz}$, Offset $=10 \mathrm{MHz}$, RMS $=-12 \mathrm{dBFS}$, Temperature $=25^{\circ} \mathrm{C}$


Figure 107. Transmitter Output Spurious, Transmitter $2=2850 \mathrm{MHz}$, $L T E=5 \mathrm{MHz}$, Offset $=10 \mathrm{MHz}, R M S=-12 \mathrm{dBFS}$, Temperature $=25^{\circ} \mathrm{C}$


Figure 108. Observation Receiver Matching Circuit Path Loss vs. LO Frequency, Can be Used for De-Embedding Performance Data


Figure 109. Observation Receiver LO Leakage vs. Transmitter LO Frequency


Figure 110. Observation Receiver Noise Figure vs. Observation Receiver LO Frequency, Total Nyquist Integration Bandwidth


Figure 111. Observation Receiver IIP2, Sum and Difference Products vs. Swept Pass Band Frequency, Tones Separated by 1 MHz Swept Across Pass Band at -19 dBm Each, $\mathrm{LO}=650 \mathrm{MHz}$, Attenuation $=0 \mathrm{~dB}$


Figure 112. Observation Receiver IIP2, Sum and Difference Products vs. Swept Pass Band Frequency, Tones Separated by 1 MHz Swept Across Pass Band at -19 dBm Each, $\mathrm{LO}=1800 \mathrm{MHz}$, Attenuation $=0 \mathrm{~dB}$


Figure 113. Observation Receiver IIP2, Sum and Difference Products vs. Swept Pass Band Frequency, Tones Separated by 1 MHz Swept Across Pass Band at -19 dBm Each, $L O=2850 \mathrm{MHz}$, Attenuation $=0 \mathrm{~dB}$,


Figure 114. Observation Receiver IIP2, Sum and Difference Products vs. Observation Receiver Attenuation, Tone $1=1845 \mathrm{MHz}$, Tone $2=1846 \mathrm{MHz}$ at -19 dBm Plus Attenuation, $\mathrm{LO}=1800 \mathrm{MHz}$


Figure 115. Observation Receiver IIP2, f1 - f2 vs. f2 Offset Frequency, LO = 650 MHz , Tone $1=652 \mathrm{MHz}$, Tone $2=$ Swept at -19 dBm Each, Observation Receiver Attenuation $=0 \mathrm{~dB}$


Figure 116. Observation Receiver IIP2,f1 - f2 vs. f2 Offset Frequency, LO = 1800 MHz , Tone $1=1802 \mathrm{MHz}$, Tone 2 = Swept at -19 dBm Each, Attenuation $=0 d B$


Figure 117. Observation Receiver IIP2,f1 - f2 vs. f2 Offset Frequency, LO = 2850 MHz , Tone $1=2852 \mathrm{MHz}$, Tone 2 = Swept at -19 dBm Each, Attenuation $=0 d B$


Figure 118. Observation Receiver IIP2, f1 - f2 vs. Observation Receiver Attenuation, $\mathrm{LO}=1800 \mathrm{MHz}$, Tone $1=1802 \mathrm{MHz}$, Tone $2=1902 \mathrm{MHz}$ at -19 dBm Plus Attenuation


Figure 119. Observation Receiver IIP3, $2 f 1$ - f2 vs. f1 Offset Frequency, LO = 650 MHz , Attenuation $=0 \mathrm{~dB}$, Tones Separated by 1 MHz Swept Across Pass Band at-19dBm Each


Figure 120. Observation Receiver IIP3, $2 f 1$ - f2 vs. f1 Offset Frequency, LO = 1800 MHz, Attenuation $=0$ dB, Tones Separated by 1 MHz Swept Across Pass Band at-19dBm Each


Figure 121. Observation Receiver IIP3, 2f1-f2 vs. f1 Offset Frequency, LO = 2850 MHz, Attenuation $=0$ dB, Tones Separated by 1 MHz Swept Across Pass Band at - 19 dBm Each


Figure 122. Observation Receiver IIP3, $2 f 1$ - f2 vs. Observation Receiver Attenuation, LO = 1800 MHz , Tone $1=1895 \mathrm{MHz}$, Tone $2=1896 \mathrm{MHz}$ at -19 dBm Plus Attenuation


Figure 123. Observation Receiver IIP3, $2 f 1$ - f2 vs. Intermodulation Frequency, LO $=650 \mathrm{MHz}$, Tone $1=652 \mathrm{MHz}$, Tone $2=$ Swept at -19 dBm Each


Figure 124. Observation Receiver IIP3, 2f1-f2 vs. Intermodulation Frequency, LO = 1800 MHz , Tone $1=1802 \mathrm{MHz}$, Tone 2 = Swept at -19 dBm Each


Figure 125. Observation Receiver IIP3, 2f1-f2 vs. Intermodulation Frequency, LO $=2850 \mathrm{MHz}$, Tone $1=2852 \mathrm{MHz}$, Tone $2=$ Swept at -19 dBm Each


Figure 126. Observation Receiver IIP3, $2 f 1$ - f2 vs. Observation Receiver Attenuation, LO = 1800 MHz , Tone $1=1802 \mathrm{MHz}$, Tone 2 = 1922 MHz at -19 dBm Plus Attenuation


Figure 127. Observation Receiver Image Rejection vs. Baseband Frequency Offset, CW Signal Swept Across the Band, $L O=650 \mathrm{MHz}$


Figure 128. Observation Receiver Image Rejection vs. Baseband Frequency Offset, CW Signal Swept Across the Band, LO $=1850 \mathrm{MHz}$


Figure 129. Observation Receiver Image Rejection vs. Baseband Frequency Offset, CW Signal Swept Across the Band, $L O=2850 \mathrm{MHz}$


Figure 130. Observation Receiver Gain vs. Observation Receiver Attenuation, $L O=650 \mathrm{MHz}$


Figure 131. Observation Receiver Gain vs. Observation Receiver Attenuation, $L O=1800 \mathrm{MHz}$


Figure 132. Observation Receiver Gain vs. Observation Receiver Attenuation, LO $=2800 \mathrm{MHz}$


Figure 133. Observation Receiver Attenuator Step Accuracy vs. Observation Receiver Attenuator Setting, LO $=2600 \mathrm{MHz}$


Figure 134. Observation Receiver Pass Band Flatness vs. Baseband Frequency Offset, $\mathrm{LO}=1800 \mathrm{MHz}$


Figure 135. Observation Receiver DC Offset vs. Observation Receiver Attenuation, $\mathrm{LO}=1850 \mathrm{MHz}$


Figure 136. Observation Receiver HD2 vs. Offset Frequency and Attenuation, $L O=650 \mathrm{MHz}$, Tone Level $=-20 \mathrm{dBm}$ at Attenuation $=0 \mathrm{~dB}$


Figure 137. Observation Receiver HD2 vs. Offset Frequency and Attenuation, $L O=1850 \mathrm{MHz}$, Tone Level $=-20 \mathrm{dBm}$ at Attenuation $=0 \mathrm{~dB}$


Figure 138. Observation Receiver HD2 vs. Offset Frequency and Attenuation, $L O=2850 \mathrm{MHz}$, Tone Level $=-20 \mathrm{dBm}$ at Attenuation $=0 \mathrm{~dB}$


Figure 139. Observation Receiver HD3, Left and Right vs. Offset Frequency, $L O=650 \mathrm{MHz}$, Tone Level $=-20 \mathrm{dBm}$ at Attenuation $=0 \mathrm{~dB}$


Figure 140. Observation Receiver HD3, Left and Right vs. Offset Frequency, $L O=1850 \mathrm{MHz}$, Tone Level $=-20 \mathrm{dBm}$ at Attenuation $=0 \mathrm{~dB}$


Figure 141. Observation Receiver HD3, Left and Right vs. Offset Frequency, LO $=2850 \mathrm{MHz}$, Tone Level $=-20 \mathrm{dBm}$ at Attenuation $=0 \mathrm{~dB}$


Figure 142. Observation Receiver HD3, Left and Right vs. Offset Frequency, $L O=1850 \mathrm{MHz}$, Observation Receiver Attenuation $=0 \mathrm{~dB}$ and 11.5 dB


Figure 143. Transmitter to Observation Receiver Isolation vs. LO Frequency, Temperature $=25^{\circ} \mathrm{C}$


Figure 144. LO Phase Noise vs. Frequency Offset, $L O=1900$ MHz, Spectrum Analyzer Limits Far Out Noise

## 3400 MHz TO 4800 MHz BAND



Figure 145. Transmitter Path Loss vs. LO Frequency (Simulation), Can be Used for De-Embedding Performance Data


Figure 146. Transmitter Continuous Wave Output Power vs. Transmitter LO Frequency, Transmitter QEC and External LO Leakage Active, Transmitter in $200 \mathrm{MHz} / 450 \mathrm{MHz}$ Bandwidth Mode, IQ Rate $=491.52 \mathrm{MHz}$, Attenuation $=0 \mathrm{~dB}$, Not De-Embedded


Figure 147. Transmitter Image Rejection vs. Baseband Offset Frequency and Attenuation, QEC Trained with Three Tones Placed at $10 \mathrm{MHz}, 50 \mathrm{MHz}$, and 100 MHz (Tracking On), Total Combined Power $=-6$ dBFS, Correction Then Frozen (Tracking Turned Off), Continuous Wave Tone Swept Across Large Signal Bandwidth, $\mathrm{LO}=3700 \mathrm{MHz}$


Figure 148. Transmitter Image Rejection vs. Baseband Offset Frequency and Attenuation, QEC Trained with Three Tones (Tracking On), Total Combined Power $=-6 d B F S$, Correction Then Frozen (Tracking Turned Off), Continuous Wave Tone Swept Across Large Signal Bandwidth, $L O=4600 \mathrm{MHz}$


Figure 149. Transmitter Pass Band Flatness vs. Baseband Offset Frequency, Off Chip Match Response De-Embedded, $\mathrm{LO}=3600 \mathrm{MHz}$


Figure 150. Transmitter Pass Band Flatness vs. Baseband Offset Frequency, Off Chip Match Response De-Embedded, $\mathrm{LO}=4600 \mathrm{MHz}$


Figure 151. Transmitter LO Leakage vs. Transmitter LO Frequency, Transmitter Attenuation $=0 \mathrm{~dB}$


Figure 152. Transmitter to Transmitter Isolation vs. Transmitter LO Frequency, Temperature $=25^{\circ} \mathrm{C}$


Figure 153. Transmitter Noise vs. Transmitter Attenuator Setting


Figure 154. Transmitter OIP3, Right vs. Transmitter Attenuator Setting, $L O=3600 \mathrm{MHz}$, Total RMS Power $=-12 \mathrm{dBFS}$.


Figure 155. Transmitter OIP3, Right vs. Transmitter Attenuator Setting, $L O=4600 \mathrm{MHz}$, Total RMS Power $=-12 \mathrm{dBFS}$


Figure 156. Transmitter OIP3, Right vs. Baseband Tone Pair Swept Across Pass Band, $L O=3600 \mathrm{MHz}$, Total RMS Power $=-12 \mathrm{dBFS}$


Figure 157. Transmitter OIP3, Right vs. Baseband Tone Pair Swept Across Pass Band, $L O=4600 \mathrm{MHz}$, Total RMS Power $=-12 \mathrm{dBFS}$


Figure 158. Transmitter HD2 vs. Transmitter Attenuator Setting, Baseband Frequency $=10 \mathrm{MHz}, L O=3600 \mathrm{MHz}, C W=-15 \mathrm{dBFS}$


Figure 159. Transmitter HD2 vs. Transmitter Attenuator Setting, Baseband Frequency $=10 \mathrm{MHz}, L O=4600 \mathrm{MHz}, C W=-15 \mathrm{dBFS}$


Figure 160. Transmitter HD3 vs. Transmitter Attenuator Setting, $L O=3600 \mathrm{MHz}, \mathrm{CW}=-15 \mathrm{dBFS}$, Baseband Frequency $=10 \mathrm{MHz}$


Figure 161. Transmitter HD3 vs. Transmitter Attenuator Setting, $L O=4600 \mathrm{MHz}, C W=-15 \mathrm{dBFS}$, Baseband Frequency $=10 \mathrm{MHz}$


Figure 162. Transmitter HD3 Image Appears on Same Side as Desired Signal vs. Transmitter Attenuator Setting, $L O=3600 \mathrm{MHz}, C W=-15 \mathrm{dBFS}$


Figure 163. Transmitter HD3 Image Appears on Same Side as Desired Signal vs. Transmitter Attenuator Setting, $L O=4600 \mathrm{MHz}, C W=-15 \mathrm{dBFS}$


Figure 164. Transmitter Attenuator Step Error vs. Transmitter Attenuator Setting, LO $=3600 \mathrm{MHz}$


Figure 165. Transmitter Attenuator Step Error vs. Transmitter Attenuator Setting, LO $=4600 \mathrm{MHz}$


Figure 166. Transmitter EVM vs. Transmitter Attenuation, LTE $=20 \mathrm{MHz}$, Signal Centered on DC, $L O=3600 \mathrm{MHz}$


Figure 167. Transmitter EVM vs. Transmitter Attenuation, $L T E=20 \mathrm{MHz}$, Signal Centered on DC, LO $=4600 \mathrm{MHz}$


Figure 168. Amplitude vs. Frequency, Transmitter Output Spurious, Transmitter $1=4600 \mathrm{MHz}$, LTE $=5 \mathrm{MHz}$, Offset $=10 \mathrm{MHz}$, RMS Ripple in Noise Floor due to Spectrum Analyzer $=-12 \mathrm{dBFS}$, Temperature $=25^{\circ} \mathrm{C}$


Figure 169. Observation Receiver Off Chip Matching Circuit Path Loss vs. LO Frequency (Simulation), Can be Used for De-Embedding Performance Data


Figure 170. Observation Receiver LO Leakage vs. LO Frequency from 3600 MHz to 4600 MHz


Figure 171. Observation Receiver Noise Figure vs. Observation Receiver Attenuator Setting, LO = 3600 MHz , Total Nyquist Integration Bandwidth


Figure 172. Observation Receiver Noise Figure vs. Observation Receiver Attenuator Setting, LO $=4600 \mathrm{MHz}$, Total Nyquist Integration Bandwidth


Figure 173. Observation Receiver IIP2, Sum and Difference Products vs. f1 Offset Frequency, Tones Separated by 1 MHz Swept Across Pass Band at -22 dBm Each, LO $=3600 \mathrm{MHz}$, Attenuation $=0 \mathrm{~dB}$


Figure 174. Observation Receiver IIP2, Sum and Difference Products vs. f1 Offset Frequency, Tones Separated by 1 MHz Swept Across Pass Band at -22 dBm Each, $\mathrm{LO}=4600 \mathrm{MHz}$, Attenuation $=0 \mathrm{~dB}$


Figure 175. Observation Receiver IIP2, Sum and Difference Products vs. Observation Receiver Attenuation, LO = 3600 MHz , Tone $1=3645 \mathrm{MHz}$, Tone $2=3646 \mathrm{MHz}$ at -22 dBm Plus Attenuation


Figure 176. Observation Receiver IIP2, Sum and Difference Products vs. Observation Receiver Attenuation, LO $=4600 \mathrm{MHz}$, Tone $1=4645 \mathrm{MHz}$, Tone $2=4646 \mathrm{MHz}$ at -22 dBm Plus Attenuation


Figure 177. Observation Receiver IIP2, f1-f2 vs. Intermodulation Frequency, $L O=3600 \mathrm{MHz}$, Tone $1=3602 \mathrm{MHz}$, Tone 2 = Swept, -22 dBm Each, Attenuation $=0 \mathrm{~dB}$


Figure 178. Observation Receiver IIP2, f1 - f2 vs. Intermodulation Frequency, $L O=4600 \mathrm{MHz}$, Tone $1=4602 \mathrm{MHz}$, Tone 2 = Swept, -22 dBm Each, Attenuation $=0 \mathrm{~dB}$


Figure 179. Observation Receiver IIP2,f1 - f2 vs. Observation Receiver Attenuation, $\mathrm{LO}=3600 \mathrm{MHz}$, Tone $1=3602 \mathrm{MHz}$, Tone $2=3702 \mathrm{MHz}$ at -22 dBm Plus Attenuation


Figure 180. Observation Receiver IIP2, f1 - f2 vs. Observation Receiver Attenuation, $L O=4600 \mathrm{MHz}$, Tone $1=4602 \mathrm{MHz}$, Tone $2=4612 \mathrm{MHz}$ at -22 dBm Plus Attenuation


Figure 181. Observation Receiver IIP3, f1 - f2 vs.f1 Offset Frequency, LO = 3600 MHz, Attenuation $=0$ dB, Tones Separated by 1 MHz Swept Across Pass Band at - 22 dBm Each


Figure 182. Observation Receiver IIP3, $2 f 1$ - f2 vs. f1 Offset Frequency, LO $=4600 \mathrm{MHz}$, Attenuation $=0 \mathrm{~dB}$, Tones Separated by 1 MHz Swept Across Pass Band at - 22 dBm Each


Figure 183. Observation Receiver IIP3, 2f1 - f2 vs. Observation Receiver Attenuation, $\mathrm{LO}=3600 \mathrm{MHz}$, Tone $1=3695 \mathrm{MHz}$, Tone $2=3696 \mathrm{MHz}$ at -22 dBm Plus Attenuation


Figure 184. Observation Receiver IIP3, 2f1-f2 vs. Observation Receiver Attenuation, $\mathrm{LO}=4600 \mathrm{MHz}$, Tone $1=4695 \mathrm{MHz}$, Tone $2=4696 \mathrm{MHz}$ at -22 dBm Plus Attenuation


Figure 185. Observation Receiver IIP3, 2f1 - f2 vs. Intermodulation Frequency, LO $=3600 \mathrm{MHz}$, Tone $1=3602 \mathrm{MHz}$, Tone $2=$ Swept, -22 dBm Each


Figure 186. Observation Receiver IIP3, $2 f 1$ - f2 vs. Intermodulation Frequency, LO $=4600 \mathrm{MHz}$, Tone $1=4602 \mathrm{MHz}$, Tone 2 Swept, -22 dBm Each


Figure 187. Observation Receiver IIP3, $2 f 1$ to f2 vs. Observation Receiver Attenuation, LO $=3600 \mathrm{MHz}$, Tone $1=3602 \mathrm{MHz}$, Tone $2=3722 \mathrm{MHz}$, -22 dBm Plus Attenuation Each


Figure 188. Observation Receiver IIP3, $2 f 1$ - f2 vs. Observation Receiver Attenuation, $\mathrm{LO}=4600 \mathrm{MHz}$, Tone $1=4602 \mathrm{MHz}$, Tone $2=4722 \mathrm{MHz}$ at -22 dBm Plus Attenuation Each


Figure 189. Observation Receiver Image Rejection vs. Baseband Frequency Offset, CW Signal Swept Across the Band, LO = 3600 MHz


Figure 190. Observation Receiver Image Rejection vs. Baseband Frequency Offset, CW Signal Swept Across the Band, $L O=4600 \mathrm{MHz}$


Figure 191. Observation Receiver Gain vs. Observation Receiver Attenuation, $L O=3600 \mathrm{MHz}$


Figure 192. Observation Receiver Gain vs. Observation Receiver Attenuation, $L O=4600 \mathrm{MHz}$


Figure 193. Observation Receiver Gain Step Error vs. Observation Receiver Attenuator Setting, LO $=3600 \mathrm{MHz}$


Figure 194. Observation Receiver Gain Step Error vs. Observation Receiver Attenuator Setting, LO $=4600 \mathrm{MHz}$


Figure 195. Observation Receiver Pass Band Flatness vs. Baseband Frequency Offset, LO = 3600 MHz


Figure 196. Observation Receiver Pass Band Flatness vs. Baseband Frequency Offset, LO = 4600 MHz


Figure 197. Observation Receiver DC Offset vs. Observation Receiver
Attenuation, $\mathrm{LO}=3600 \mathrm{MHz}$


Figure 198. Observation Receiver DC Offset vs. Observation Receiver
Attenuation, $\mathrm{LO}=4600 \mathrm{MHz}$


Figure 199. Observation Receiver HD2 vs. Offset Frequency, LO = 3600 MHz , Tone Level $=-20 \mathrm{dBm}$ Plus Attenuation


Figure 200. Observation Receiver HD2 vs. Offset Frequency, $L O=4600 \mathrm{MHz}$, Tone Level $=-20 \mathrm{dBm}$ Plus Attenuation


Figure 201. Observation Receiver HD3, Left and Right vs. Offset Frequency, $L O=3600 \mathrm{MHz}$, Tone Level $=-20 \mathrm{dBm}$


Figure 202. Observation Receiver HD3, Left and Right vs. Offset Frequency, $L O=4600 \mathrm{MHz}$, Tone Level $=-20 \mathrm{dBm}$


Figure 203. Transmitter to Observation Receiver Isolation vs. LO Frequency, Temperature $=25^{\circ} \mathrm{C}$


Figure 204. LO Phase Noise vs. Frequency Offset, LO = 3800 MHz , PLL Loop Bandwidth $=300$ kHz, Spectrum Analyzer Limits Far Out Noise

## 5100 MHz TO 5900 MHz BAND



Figure 205. Transmitter Path Loss vs. LO Frequency (Simulation), Useful for De-Embedding Performance Data


Figure 206. Transmitter CW Output Power vs. Transmitter LO Frequency, Transmitter QEC, and External LO Leakage Active, Bandwidth Mode = $200 \mathrm{MHz} / 450 \mathrm{MHz}$, $\operatorname{lQ}$ Rate $=491.52 \mathrm{MHz}$, Attenuation $=0 \mathrm{~dB}$, Not De-Embedded


Figure 207. Transmitter Image Rejection vs. Baseband Offset Frequency, QEC Enabled (Tracking On) with Three Tones Placed at $10 \mathrm{MHz}, 50 \mathrm{MHz}$, and 100 MHz Offset from LO, Total Combined Power $=-6$ dBFS, Correction Then Frozen (Tracking Turned Off), CW Tone Swept Across Large Signal Bandwidth, $\mathrm{LO}=5100 \mathrm{MHz}$


Figure 208. Transmitter Image Rejection vs. Baseband Offset Frequency, QEC Trained with Three Tones Placed at $10 \mathrm{MHz}, 50 \mathrm{MHz}$, and 100 MHz (Tracking On), Total Combined Power $=-6$ dBFS, Correction Then Frozen (Tracking Turned Off), CW Tone Swept Across Large Signal Bandwidth, LO =5500 MHz


Figure 209. Transmitter Image Rejection vs. Baseband Offset Frequency, QEC Trained with Three Tones Placed at $10 \mathrm{MHz}, 50 \mathrm{MHz}$, and 100 MHz (Tracking On), Total Combined Power $=-6$ dBFS, Correction Then Frozen (Tracking Turned Off), CW Tone Swept Across Large Signal Bandwidth, LO = 5900 MHz


Figure 210. Transmitter Pass Band Flatness vs. Baseband Offset Frequency, Off Chip Match Response De-Embedded, $L O=5700 \mathrm{MHz}$, Measurements Performed with Device Calibrated at $25^{\circ} \mathrm{C}$


Figure 211. Transmitter LO Leakage vs. Transmitter LO Frequency, Transmitter Attenuation $=0 \mathrm{~dB}$


Figure 212. Transmitter to Transmitter Isolation vs. Transmitter LO Frequency, Temperature $=25^{\circ} \mathrm{C}$


Figure 213. Transmitter Noise vs. Transmitter Attenuator Setting


Figure 214. Transmitter Adjacent Channel Leakage Ratio vs. Transmitter Attenuator Setting, LO $=5100 \mathrm{MHz}, L T E=20 \mathrm{MHz}, P A R=12 \mathrm{~dB}$, DAC Boost Normal, Upper Side and Lower Side, Decreasing ACLR at Higher Attenuation due to Spectrum Analyzer Noise Floor


Figure 215. Transmitter Adjacent Channel Leakage Ratio vs. Transmitter Attenuator Setting, LO $=5500 \mathrm{MHz}, L T E=20 \mathrm{MHz}, P A R=12 \mathrm{~dB}$, DAC Boost Normal, Upper Side and Lower Side, Decreasing ACLR at Higher Attenuation Due to Spectrum Analyzer Noise Floor


Figure 216. Transmitter Adjacent Channel Leakage Ratio vs. Transmitter Attenuator Setting, LO $=5900 \mathrm{MHz}, L T E=20 \mathrm{MHz}, P A R=12 \mathrm{~dB}, \mathrm{DAC}$ Boost Normal, Upper Side and Lower Side, Decreasing ACLR at Higher Attenuation Due to Spectrum Analyzer Noise Floor


Figure 217. Transmitter OIP3, Right vs. Transmitter Attenuator Setting, $L O=5100 \mathrm{MHz}$, Total RMS Power $=-12 \mathrm{dBFS}$


Figure 218. Transmitter OIP3, Right vs. Transmitter Attenuator Setting, $L O=5500 \mathrm{MHz}$, Total RMS Power $=-12 \mathrm{dBFS}$


Figure 219. Transmitter OIP3, Right vs. Transmitter Attenuator Setting, $L O=5800 \mathrm{MHz}$, Total RMS Power $=-12 \mathrm{dBFS}$


Figure 220. Transmitter OIP3, Right vs. Baseband Frequency Offset, LO $=5100 \mathrm{MHz}$, Total RMS Power $=-12$ dBFS Power, Transmitter Attenuation $=4 \mathrm{~dB}$


Figure 221. Transmitter OIP3, Right vs. Baseband Frequency Offset, LO $=5500 \mathrm{MHz}$, Total RMS Power $=-12$ dBFS, Transmitter Attenuation $=$ $4 d B$


Figure 222. Transmitter OIP3, Right vs. Baseband Frequency Offset, LO $=5900 \mathrm{MHz}$, Total RMS Power $=-12$ dBFS, Transmitter Attenuation $=4 \mathrm{~dB}$


Figure 223. Transmitter HD2 vs. Transmitter Attenuator Setting, Baseband Frequency $=10 \mathrm{MHz}, \mathrm{LO}=5100 \mathrm{MHz}, C W=-15 \mathrm{dBFS}$


Figure 224. Transmitter HD2 vs. Transmitter Attenuator Setting, Baseband Frequency $=10 \mathrm{MHz}, L O=5500 \mathrm{MHz}, C W=-15 \mathrm{dBFS}$


Figure 225. Transmitter HD2 vs. Transmitter Attenuator Setting, Baseband Frequency $=10 \mathrm{MHz}, L O=5900 \mathrm{MHz}, C W=-15 \mathrm{dBFS}$


Figure 226. Transmitter HD3 on Opposite Sideband vs. Transmitter Attenuator Setting, $L O=5100 \mathrm{MHz}, C W=-15 \mathrm{dBFS}$, Baseband Frequency = 10 MHz


Figure 227. Transmitter HD3 on Opposite Sideband vs. Transmitter Attenuator Setting, $L O=5500 \mathrm{MHz}, C W=-15 \mathrm{dBFS}$, Baseband Frequency = 10 MHz


Figure 228. Transmitter HD3 on Opposite Sideband vs. Transmitter Attenuator Setting, $L O=5900 \mathrm{MHz}, C W=-15 \mathrm{dBFS}$, Baseband Frequency = 10 MHz


Figure 229. Transmitter HD3 on Same Sideband as Signal vs. Transmitter Attenuation Setting, LO $=5100 \mathrm{MHz}, \mathrm{CW}=-15 \mathrm{dBFS}$


Figure 230. Transmitter HD3 on Same Sideband as Signal vs. Transmitter Attenuator Setting, LO $=5500 \mathrm{MHz}, C W=-15 \mathrm{dBFS}$


Figure 231. Transmitter HD3 on Same Sideband as Signal vs. Transmitter Attenuator Setting, LO $=5900 \mathrm{MHz}, \mathrm{CW}=-15 \mathrm{dBFS}$


Figure 232. Transmitter Attenuator Step Error vs. Transmitter Attenuator Setting, $L O=5100 \mathrm{MHz}$


Figure 233. Transmitter Attenuator Step Error vs. Transmitter Attenuator Setting, $L O=5500 \mathrm{MHz}$


Figure 234. Transmitter Attenuator Step Error vs. Transmitter Attenuator Setting, LO = 5900 MHz


Figure 235. Transmitter EVM vs. Transmitter Attenuation, LTE $=20 \mathrm{MHz}$, Signal Centered on DC, LO $=5100 \mathrm{MHz}$


Figure 236. Transmitter EVM vs. Transmitter Attenuation, LTE $=20 \mathrm{MHz}$, Signal Centered on DC, LO =5500 MHz


Figure 237. Transmitter EVM vs. Transmitter Attenuation, $L T E=20 \mathrm{MHz}$, Signal Centered on DC, LO =5900 MHz


Figure 238. Observation Receiver Path Loss vs. LO Frequency (Simulation), Can be Used for De-Embedding Performance Data


Figure 239. Observation Receiver LO Leakage vs. LO Frequency, 5200 MHz, 5500 MHz , and 5900 MHz


Figure 240. Observation Receiver Noise Figure vs. Observation Receiver Attenuator Setting, LO = 5200 MHz, Total Nyquist Integration Bandwidth


Figure 241. Observation Receiver Noise Figure vs. Observation Receiver Attenuator Setting, LO = 5500 MHz , Total Nyquist Integration Bandwidth


Figure 242. Observation Receiver Noise Figure vs. Observation Receiver Attenuator Setting, LO = 5800 MHz , Total Nyquist Integration Bandwidth


Figure 243. Observation Receiver IIP2, Sum and Difference Products vs. f1 Offset Frequency, Tones Separated by 1 MHz Swept Across Pass Band at - 19 dBm Each, $L O=5700 \mathrm{MHz}$, Attenuation $=0 \mathrm{~dB}$


Figure 244. Observation Receiver IIP2, Sum and Difference Products vs. Observation Receiver Attenuation, LO $=5700 \mathrm{MHz}$, Tone $1=5725 \mathrm{MHz}$, Tone $2=5726 \mathrm{MHz}$ at -19 dBm Plus Attenuation


Figure 245. Observation Receiver IIP2, f1-f2 vs. Intermodulation Frequency, $L O=5700 \mathrm{MHz}$, Tone $1=5702 \mathrm{MHz}$, Tone 2 Swept,
-19 dBm Each, Attenuation $=0 \mathrm{~dB}$


Figure 246. Observation Receiver IIP2,f1-f2 vs. Observation Receiver Attenuation, $\mathrm{LO}=5700 \mathrm{MHz}$, Tone $1=5702 \mathrm{MHz}$, Tone $2=5802 \mathrm{MHz}$ at -19 dBm Plus Attenuation


Figure 247. Observation Receiver IIP3, 2f1 - f2 vs. f1 Offset Frequency, $L O=5700 \mathrm{MHz}$, Attenuation $=0 \mathrm{~dB}$, Tones Separated by 1 MHz Swept Across Pass Band at -19 dBm Each


Figure 248. Observation Receiver IIP3, $2 f 1$ - f2 vs. Observation Receiver Attenuation, $\mathrm{LO}=5700 \mathrm{MHz}$, Tone $1=5745 \mathrm{MHz}$, Tone $2=5746 \mathrm{MHz}$ at -19 dBm Plus Attenuation


Figure 249. Observation Receiver IIP3, $2 f 1$ - f2 vs. f1 Offset Frequency, $L O=5700 \mathrm{MHz}$, Tone $1=5702 \mathrm{MHz}$, Tone $2=5722 \mathrm{MHz}$ at -22 dBm Plus Attenuation Each


Figure 250. Observation Receiver IIP3, $2 f 1$ - f2 vs. Observation Receiver Attenuation, $L O=5700 \mathrm{MHz}$, Tone $1=5702 \mathrm{MHz}$, Tone $2=5822 \mathrm{MHz}$ at -19 dBm Plus Attenuation


Figure 251. Observation Receiver Image Rejection vs. Baseband Frequency Offset Attenuation, CW Signal Swept Across the Band, LO =5200 MHz


Figure 252. Observation Receiver Image Rejection vs. Baseband Frequency Offset, CW Signal Swept Across the Band, LO $=5700 \mathrm{MHz}$


Figure 253. Observation Receiver Gain vs. Observation Receiver Attenuation, $L O=5200 \mathrm{MHz}$


Figure 254. Observation Receiver Gain vs. Observation Receiver Attenuation, $L O=5700 \mathrm{MHz}$


Figure 255. Observation Receiver Gain Step Error vs. Observation Receiver Attenuator Setting, LO = 5200 MHz


Figure 256. Observation Receiver Gain Step Error vs. Observation Receiver Attenuator Setting, LO = 5600 MHz


Figure 257. Observation Receiver Gain Step Error vs. Observation Receiver Attenuator Setting, $L O=5600 \mathrm{MHz}$


Figure 258. Observation Receiver Pass Band Flatness vs. Baseband Offset Frequency, LO =5700 MHz


Figure 259. Observation Receiver HD2 vs. Offset Frequency, LO = 5200 MHz , Tone Level $=-20 \mathrm{dBm}$ Plus Attenuation


Figure 260. Observation Receiver HD2 vs. Offset Frequency, $L O=5700 \mathrm{MHz}$, Tone Level $=-20 \mathrm{dBm}$ Plus Attenuation


Figure 261. Observation Receiver HD3, Left and Right vs. Offset Frequency, $L O=5200 \mathrm{MHz}$, Tone Level $=-20 \mathrm{dBm}$


Figure 262. Observation Receiver HD3, Left and Right vs. Offset Frequency, $L O=5700 \mathrm{MHz}$, Tone Level $=-20 \mathrm{dBm}$


Figure 263. Transmitter to Observation Receiver Isolation vs. LO Frequency, Temperature $=25^{\circ} \mathrm{C}$


Figure 264. LO Phase Noise vs. Frequency Offset, $L O=5900 \mathrm{MHz}$, PLL Loop Bandwidth > 300 kHz, Spectrum Analyzer Limits Far Out Noise

## TRANSMITTER OUTPUT IMPEDANCE



Figure 265. Transmitter Output Impedance Series Equivalent Differential Impedance (SEDZ)

## OBSERVATION RECEIVER INPUT IMPEDANCE



Figure 266. Observation Receiver Input Impedance SEDZ

## TERMINOLOGY

## Large Signal Bandwidth

Large signal bandwidth, otherwise known as instantaneous bandwidth or signal bandwidth, is the bandwidth over which there are large signals. For example, for Band 42 LTE, the large signal bandwidth is 200 MHz .

Occupied Bandwidth
Occupied bandwidth is the total bandwidth of the active signals. For example, three 20 MHz carriers have a 60 MHz occupied bandwidth, regardless of where the carriers are placed within the large signal bandwidth.

## Synthesis Bandwidth

Synthesis bandwidth is the bandwidth over which digital predistortion (DPD) linearization is transmitted. Synthesis bandwidth is the 1 dB bandwidth of the transmitter. The power density of the signal outside the occupied bandwidth is assumed to be 25 dB below the signal in the occupied bandwidth, which also assumes that the unlinearized power amplifier (PA) achieves 25 dB ACLR.

## Observation Bandwidth

Observation bandwidth is the 1 dB bandwidth of the observation receiver. With the observation receiver sharing the transmitter LO, the observation receiver sees similar power densities, such as those in the occupied bandwidth and synthesis bandwidth of the transmitter.

## Backoff

Backoff is the difference (in dB ) between full scale and the rms signal power.

## $\mathbf{P}_{\text {High }}$

$\mathrm{P}_{\text {High }}$ is the largest signal that can be applied without overloading the ADC for the observation receiver input. This input level results in slightly less than full scale at the digital output because of the nature of the continuous time $\Sigma-\Delta$ ADCs, which, for example, exhibit a soft overload in contrast to the hard clipping of pipeline ADCs.

## THEORY OF OPERATION

The ADRV9008-2 is a highly integrated RF transmitter subsystem capable of configuration for a wide range of applications. The device integrates all RF, mixed-signal, and digital blocks necessary to provide all transmitter traffic and DPD observation receiver functions in a single device.
Programmability allows the transmitter to be adapted for use in many time division duplexes (TDDs) and 2G/3G/4G/5G cellular standards. The ADRV9008-2 contains four high speed serial interface links for the transmitter chain, and four high speed links for the observation receiver chain. The links are JESD204B, Subclass 1 compliant.
The ADRV9008-2 also provides tracking correction of dc offset QEC errors, and transmitter LO leakage to maintain high performance under varying temperatures and input signal conditions. The device also includes test modes that allow system designers to debug designs during prototyping and to optimize radio configurations.

## TRANSMITTER

The ADRV9008-2 transmitter section consists of two identical and independently controlled channels that provide all digital processing, mixed-signal, and RF blocks necessary to implement a direct conversion system while sharing a common frequency synthesizer. The digital data from the JESD204B lanes pass through a fully programmable, 128 -tap FIR filter with variable interpolation rates. The FIR output is sent to a series of interpolation filters that provide additional filtering and interpolation prior to reaching the DAC. Each 14-bit DAC has an adjustable sample rate.
When converted to baseband analog signals, the inphase (I) and quadrature ( Q ) signals are filtered to remove sampling artifacts and are fed to the upconversion mixers. Each transmitter chain provides a wide attenuation adjustment range with fine granularity to optimize SNR.

## OBSERVATION RECEIVER

The ADRV9008-2 contains an independent DPD observation receiver front end. The observation receiver shares the common frequency synthesizer with the transmitter.
The observation receiver is a direct conversion system that contains a programmable attenuator stage, followed by matched I and Q mixers, baseband filters, and ADCs.
The continuous time $\Sigma-\Delta$ ADCs have inherent antialiasing that reduces the RF filtering requirement.
The ADC outputs can be conditioned further by a series of decimation filters and a programmable FIR filter with additional decimation settings. The sample rate of each digital filter block is adjustable by changing decimation factors to produce the desired output data rate.

## CLOCK INPUT

The ADRV9008-2 requires a differential clock connected to the REF_CLK_IN_ $\pm$ pins. The frequency of the clock input must be between 10 MHz and 1000 MHz and must have very low phase noise because this signal generates the RF LO and internal sampling clocks.

## SYNTHESIZERS <br> RF PLL

The ADRV9008-2 contains a fractional-N PLL to generate the RF LO for the signal paths. The PLL incorporates an internal VCO and loop filter, requiring no external components. The LOs on multiple chips can be phase synchronized to support active antenna systems and beamforming applications.

## Clock PLL

The ADRV9008-2 contains a PLL synthesizer that generates all the baseband related clock signals and serialization/deserialization (SERDES) clocks. This PLL is programmed based on the data rate and sample rate requirements of the system.

## SERIAL PERIPHERAL INTERFACE (SPI)

The ADRV9008-2 uses an SPI interface to communicate with the baseband processor (BBP). This interface can be configured as a 4 -wire interface with dedicated receiver and transmitter ports, or it can be configured as a 3-wire interface with a bidirectional data communications port. This bus allows the BBP to set all device control parameters using a simple address data serial bus protocol.
Write commands follow a 24 -bit format. The first five bits set the bus direction and the number of bytes to transfer. The next 11 bits set the address where data is written. The final 8 bits are the data to be transferred to the specific register address.
Read commands follow a similar format with the exception that the first 16 bits are transferred on the SDIO pin and the final eight bits are read from the ADRV9008-2, either on the SDO pin in 4-wire mode or on the SDIO pin in 3-wire mode.

## JTAG BOUNDARY SCAN

The ADRV9008-2 provides support for JTAG boundary scan. Five dual function pins are associated with the JTAG interface. Use these pins, listed in Table 5, to access the on-chip test access port. To enable the JTAG functionality, set the GPIO_3 pin through the GPIO_0 pin to 1001, and then pull the TEST pin high.

## POWER SUPPLY SEQUENCE

The ADRV9008-2 requires a specific power-up sequence to avoid undesired power-up currents. In the optimal power-up sequence, the VDDD1P3_DIG and the VDDA1P3 supplies (VDDA1P3 includes all 1.3 V domains) power up first and at the same time. If these supplies cannot be powered up simultaneously, the VDDD1P3_DIG supply must power up first. Power up the

## ADRV9008-2

VDDA_3P3, VDDA1P8_BB, VDDA1P8_TX, VDDA1P3_DES, and VDDA1P3_SER supplies after the 1.3 V supplies. The VDD_INTERFACE supply can be powered up at any time. Note that no device damage occurs if this sequence is not followed. However, failure to follow this sequence may result in higher than expected power-up currents. It is also recommended to toggle the RESET signal after power stabilizes, prior to configuration. The power-down sequence is not critical. If a power-down sequence is followed, remove the VDDD1P3_DIG supply last to avoid any back biasing of the digital control lines.

## GPIO_x PINS

The ADRV9008-2 provides $19,1.8 \mathrm{~V}$ to 2.5 V GPIO signals that can be configured for numerous functions. When configured as outputs, certain pins can provide real-time signal information to the BBP, allowing the BBP to determine observation receiver performance. A pointer register selects the information that is output to these pins. Signals used for manual gain mode, calibration flags, state machine states, and various observation receiver parameters are among the outputs that can be monitored on these pins. Additionally, certain pins can be configured as inputs and used for various functions, such as setting the observation receiver gain in real time.

Twelve 3.3 V GPIO_x pins are also included on the device. These pins provide control signals to external components.

## AUXILIARY CONVERTERS AUXADC_x

The ADRV9008-2 contains an auxiliary ADC that is multiplexed to four input pins (AUXADC_x). The auxiliary ADC is 12 bits with an input voltage range of 0.05 V to VDDA_3P3-0.05 V. When enabled, the auxiliary ADC is free
running. The SPI reads provide the last value latched at the ADC output. The auxiliary ADC can also be multiplexed to a built in, diode-based temperature sensor.

## Auxiliary DAC x

The ADRV9008-2 contains 10 identical auxiliary DACs (auxiliary DAC x) that can be used for bias or other system functionality. The auxiliary DACs are 10 bits, have an output voltage range of approximately 0.7 V to VDDA_3P3-0.3 V, and have an output drive of 10 mA .

## JESD204B DATA INTERFACE

The digital data interface for the ADRV9008-2 uses JEDEC JESD204B Subclass 1 . The serial interface operates at speeds of up to 12.288 Gbps . The benefits of the JESD204B interface include a reduction in required board area for data interface routing, resulting in smaller total system size. Four high speed serial lanes are provided for the transmitter, and four high speed lanes are provided for the observation receiver. The ADRV9008-2 supports single-lane or dual-lane interfaces as well as fixed and floating point data formats for observation receiver data.

Table 6. Observation Path Interface Rates

|  |  | JESD204B |  |
| :--- | :--- | :--- | :--- |
| Bandwidth <br> (MHz) | Output Rate <br> (MSPS) | Lane Rate <br> (Mbps) | Number of <br> Lanes |
| 200 | 245.76 | 9830.4 | 1 |
| 200 | 307.2 | 12288 | 1 |
| 250 | 307.2 | 12288 | 1 |
| 450 | 491.52 | 9830.4 | 2 |
| 450 | 491.52 | 4915.2 | 4 |

Table 7. Transmitter Interface Rates (Other Output Rates, Bandwidth, and JESD204B Lanes Also Supported)

|  | Single-Channel Operation | Dual-Channel Operation |  |  |  |
| :--- | :--- | :--- | :--- | :--- | :--- |
| Bandwidth (MHz) |  | JESD204B Lane <br> Rate (Mbps) | JESD204B Number <br> of Lanes | JESD204B Lane <br> Rate (Mbps) | JESD204B Number <br> of Lanes |
| 200 | 245.76 | 9830.4 | 1 | 9830.4 | 2 |
| 200 | 307.2 | 12288 | 1 | 12288 | 2 |
| 250 | 307.2 | 12288 | 1 | 12288 | 2 |
| 450 | 491.52 | 9830.4 | 2 | 9830.4 | 4 |



Figure 267. Transmitter Datapath Filter Implementation


Figure 268. Observation Receiver Datapath Filter Implementation

## APPLICATIONS INFORMATION

## PCB LAYOUT AND POWER SUPPLY RECOMMENDATIONS

## Overview

The ADRV9008-2 device is a highly integrated RF agile transceiver with significant signal conditioning integrated on one chip. Due to the increased complexity of the device and its high pin count, careful PCB layout is important to get the optimal performance. This data sheet provides a checklist of issues to look for and guidelines on how to optimize the PCB to mitigate performance issues. The goal of this data sheet is to help achieve the optimal performance from the ADRV9008-2 while reducing board layout effort. This data sheet assumes that the reader is an experienced analog and RF engineer with an understanding of RF PCB layout and RF transmission lines. This data sheet discusses the following issues and provides guidelines for system designers to achieve the optimal performance for the ADRV9008-2:

- PCB material and stack up selection
- Fanout and trace space layout guidelines
- Component placement and routing guidelines
- RF and JESD204B transmission line layout
- Isolation techniques used on the ADRV9008-2W/PCBZ
- Power management considerations
- Unused pin instructions


## PCB MATERIAL AND STACKUP SELECTION

Figure 269 shows the PCB stackup used for the ADRV90082W/PCBZ. Table 8 and Table 9 list the single-ended and differential impedence for the stackup shown in Figure 269. The dielectric material used on the top and the bottom layers is 8 mil Rogers 4350B. The remaining dielectric layers are FR4-370 HR. The board design uses the Rogers laminate for the top and the bottom layers for the low loss tangent at high frequencies. The ground planes under the Rogers laminate (Layer 2 and Layer 13) are the reference planes for the transmission lines routed on the outer surfaces. These layers are solid copper planes without any splits under the RF traces. Layer 2 and Layer

13 are crucial to maintaining the RF signal integrity and, ultimately, the ADRV9008-2 performance. Layer 3 and Layer 12 are used to route power supply domains. To keep the RF section of the ADRV9008-2 isolated from the fast transients of the digital section, the JESD204B interface lines are routed on Layer 5 and Layer 10. Those layers have impedance control set to a $100 \Omega$ differential. The remaining digital lines from the ADRV9008-2 are routed on Inner Layer 7 and Inner Layer 8. RF traces on the outer layers must be a controlled impedance to get the best performance from the device. The inner layers on this board use 0.5 ounce copper or 1 ounce copper. The outer layers use 1.5 ounce copper so that the RF traces are less prone to pealing. Ground planes on this board are full copper floods with no splits except for vias, through-hole components, and isolation structures. The ground planes must route entirely to the edge of the PCB under the Surface-Mount Type A (SMA) connectors to maintain signal launch integrity. Power planes can be pulled back from the board edge to decrease the risk of shorting from the board edge.


Figure 269. ADRV9008-2W/PCBZ Trace Impedance and Stackup

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Table 8. Evaluation Board Single-Ended Impedance and Stackup ${ }^{1}$

| Layer | Board Copper \% | Starting Copper (oz.) | Finished Copper (oz.) | Single-Ended Impedance | Designed Trace SingleEnded (inches) | Finished <br> Trace Single- <br> Ended <br> (inches) | Calculated Impedance ( $\Omega$ ) | SingleEnded Reference Layers |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| 1 | N/A | 0.5 | 1.71 | $50 \Omega \pm 10 \%$ | 0.0155 | 0.0135 | 49.97 | 2 |
| 2 | 65 | 1 | 1 | N/A | N/A | N/A | N/A | N/A |
| 3 | 50 | 0.5 | 1 | N/A | N/A | N/A | N/A | N/A |
| 4 | 65 | 1 | 1 | N/A | N/A | N/A | N/A | N/A |
| 5 | 50 | 0.5 | 0.5 | $50 \Omega \pm 10 \%$ | 0.0045 | 0.0042 | 49.79 | 4,6 |
| 6 | 65 | 1 | 1 | N/A | N/A | N/A | N/A | N/A |
| 7 | 50 | 0.5 | 0.5 | $50 \Omega \pm 10 \%$ | 0.0049 | 0.0039 | 50.05 | 6,9 |
| 8 | 50 | 0.5 | 0.5 | $50 \Omega \pm 10 \%$ | 0.0049 | 0.0039 | 50.05 | 6,9 |
| 9 | 65 | 1 | 1 | N/A | N/A | N/A | N/A | N/A |
| 10 | 50 | 0.5 | 1 | $50 \Omega \pm 10 \%$ | 0.0045 | 0.0039 | 49.88 | 9, 11 |
| 11 | 65 | 0.5 | 1 | N/A | N/A | N/A | N/A | N/A |
| 12 | 50 | 1 | 1 | N/A | N/A | N/A | N/A | N/A |
| 13 | 65 | 1 | 1 | N/A | N/A | N/A | N/A | N/A |
| 14 |  | 0.5 | 1.64 | $50 \Omega \pm 10 \%$ | 0.0155 | 0.0135 | 49.97 | 13 |

${ }^{1} \mathrm{~N} / \mathrm{A}$ means not applicable.
Table 9. Evaluation Board Differential Impedance and Stackup ${ }^{1}$

| Layer | Differential Impedance | Designed Trace (inches) | Designed Gap Differential (inches) | Finished Trace (inches) | Finished Gap Differential (inches) | Calculated Impedance ( $\Omega$ ) | Differential Reference Layers |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| 1 | $100 \Omega \pm 10 \%$ | 0.008 | 0.006 | 0.007 | 0.007 | 99.55 | 2 |
|  | $50 \Omega \pm 10 \%$ | 0.0032 | 0.004 | 0.0304 | 0.0056 | 50.11 | 2 |
| 2 | N/A | N/A |  | N/A |  | N/A | N/A |
| 3 | N/A | N/A |  | N/A |  | N/A | N/A |
| 4 | N/A | N/A |  | N/A |  | N/A | N/A |
| 5 | $100 \Omega \pm 10 \%$ | 0.0036 | 0.0064 | 0.0034 | 0.0065 | 99.95 | 4, 6 |
| 6 | N/A | N/A |  | N/A |  | N/A | N/A |
| 7 | $100 \Omega \pm 10 \%$ | 0.0036 | 0.0064 | 0.0034 | 0.0066 | 100.51 | 6,9 |
| 8 | $100 \Omega \pm 10 \%$ | 0.0038 | 0.0062 | 0.0034 | 0.0066 | 100.51 | 6,9 |
| 9 | N/A | N/A |  | N/A |  | N/A | N/A |
| 10 | $100 \Omega \pm 10 \%$ | 0.0036 | 0.0064 | 0.003 | 0.007 | 100.80 | 9, 11 |
|  | N/A | N/A |  | N/A |  | N/A | N/A |
|  | N/A | N/A |  | N/A |  | N/A | N/A |
| 11 | N/A | N/A |  | N/A |  | N/A | N/A |
| 12 | N/A | N/A |  | N/A |  | N/A | N/A |
| 13 | $100 \Omega \pm 10 \%$ | 0.008 | 0.006 | 0.007 | 0.007 | 99.55 | 13 |
| 14 | $50 \Omega \pm 10 \%$ | 0.032 |  | 0.004 |  | 50.11 | 13 |

[^3]
## FANOUT AND TRACE SPACE GUIDELINES

The ADRV9008-2 device uses a 196-ball chip scale package ball grid array (CSP_BGA), $12 \times 12 \mathrm{~mm}$ package. The pitch between the pins is 0.8 mm . This small pitch makes it impractical to route all signals on a single layer. RF pins are placed on the outer edges of the ADRV9008-2 package. The location of the pins helps route the critical signals without a fanout via. Each digital signal is routed from the BGA pad using a 4.5 mil trace. The trace is connected to the BGA using a via in the pad structure. The signals are buried in the inner layers of the board for routing to other parts of the system.

The JESD204B interface signals are routed on two signal layers that use impedance control (Layer 5 and Layer 10). The spacing between the BGA pads is 17.5 mil. After the signal is on the inner layers, a 3.6 mil trace ( $50 \Omega$ ) connects the JESD204B signal to the field programmable gate array (FPGA) mezzanine card (FMC) connector. The recommended BGA land pad size is 15 mil .

Figure 270 shows the fanout scheme of the ADRV9008-2W/PCBZ. As mentioned before, the ADRV9008-2W/PCBZ uses a via in the pad technique. This routing approach can be used for the ADRV9008-2 if there are no issues with manufacturing capabilities.


Figure 270. Trace Fanout Scheme on the ADRV9008-2W/PCBZ (PCB Layer Top and Layer 5 Enabled)

## COMPONENT PLACEMENT AND ROUTING GUIDELINES

The ADRV9008-2 transceiver requires few external components to function, but those that are used require careful placement and routing to optimize performance. This section provides a checklist for properly placing and routing critical signals and components.

## Signals with Highest Routing Priority

RF lines and JESD204B interface signals are the signals that are most critical and must be routed with the highest priority.
Figure 271 shows the general directions in which each of the signals must be routed so that they can be properly isolated from noisy signals.

The observation receiver and transmitter baluns and the matching circuits affect the overall RF performance of the ADRV9008-2 transceiver. Make every effort to optimize the component selection and placement to avoid performance degradation. The RF Routing Guidelines section describes proper matching circuit placement and routing in more detail. Refer to the RF Port Interface Information section for more information.

To achieve the desired level of isolation between RF signal paths, use the technique described in the Isolation Techniques Used on the ADRV9008-2W/PCBZ section in customer designs.

In cases in which ADRV9008-2 is used, install a $10 \mu \mathrm{~F}$ capacitor near the transmitter balun(s) VDDA1P8_TX dc feed(s) for RF transmitter outputs. This acts as a reservoir for the transmitter supply current. The Transmitter Balun DC Feed Supplies section discusses more details about the transmitter output power supply configuration.


Figure 271. RF Input/Output, REF_CLK_IN $\pm$, and JESD204B Signal Routing Guidelines

Figure 272 shows placement for ac coupling capacitors and a $100 \Omega$ termination resistor near the ADRV9008-2 REF_CLK_IN $\pm$ pins. Shield the traces with ground flooding that is surrounded with vias staggered along the edge of the trace pair. The trace pair creates a shielded channel that shields the reference clock from any interference from other signals. Refer to the ADRV90082W/PCBZ layout, including board support files included with the evaluation board software, for exact details.

Route the JESD204B interface at the beginning of the PCB design and with the same priority as the RF signals. The RF

Routing Guidelines section outlines recommendations for JESD204B interface routing. Provide appropriate isolation between interface differential pairs. The Isolation Between JESD204B Lines section provides guidelines for optimizing isolation.

The RF_EXT_LO_I/O- pin (B7) and the RF_EXT_LO_I/O+ pin (B8) on the ADRV9008-2 are internally dc biased. If an external LO is used, connect it via ac coupling capacitors.


Figure 272. REF_CLK_IN $\pm$ Routing Recommendation

## ADRV9008-2

## Signals with Second Routing Priority

Power supply quality has direct impact on overall system performance. To achieve optimal performance, users should follow recommendations regarding ADRV9008-2 power supply routing. The following recommendations outline how to route different power domains that can be connected together directly and that can be tied to the same supply, but are separated by a $0 \Omega$ placeholder resistor or ferrite bead (FB).

When the recommendation is to use a trace to connect power to a particular domain, ensure that this trace is surrounded by ground.

Figure 273 shows an example of such traces routed on the ADRV9008-2W/PCBZ on Layer 12. Each trace is separated from any other signal by the ground plane and vias. Separating the traces from other signals is essential to providing necessary isolation between the ADRV9008-2 power domains.


Figure 273. Layout Example of Power Supply Domains Routed with Ground Shielding (Layer 12 to Power)

Each power supply pin requires a $0.1 \mu \mathrm{~F}$ bypass capacitor near the pin at a minimum. Place the ground side of the bypass capacitor so that ground currents flow away from other power pins and the bypass capacitors.
For the domains shown in Figure 274, like the domains powered through a $0 \Omega$ placeholder resistor or ferrite bead, place the $0 \Omega$ placeholder resistors or ferrite beads further away from the device. Space $0 \Omega$ placeholder resistors or ferrite beads apart from each other to ensure the electric fields on the ferrite beads do not influence each other. Figure 275 shows an example of how the ferrite beads, reservoir capacitors, and decoupling
capacitors are placed. The recommendation is to connect a ferrite bead between a power plane and the ADRV9008-2 at a distance away from the device The ferrite bead and the resevoir capacitor provide stable voltage to the ADRV9008-2 during operation by isolating the pin or pins that the network is connected to from the power plane. Then, shield that trace with ground and provide power to the power pins on the ADRV9008-2. Place a 100 nF capacitor near the power supply pin with the ground side of the bypass capacitor placed so that ground currents flow away from other power pins and the bypass capacitors.


Figure 274. Power Supply Domains Interconnection Guidelines


Figure 275. Placement Example of $0 \Omega$ Resistor Placeholders for Ferrite Beads, Reservoir and Bypass Capacitors on the ADRV9008-2W/PCBZ (Layer 12 to Power Layer and Bottom Layer)

## Signals with Lowest Routing Priority

As a last step while designing the PCB layout, route signals shown in Figure 276. The following list outlines the recommended order of signal routing:

1. Use ceramic $1 \mu \mathrm{~F}$ bypass capacitors at the VDDA1P1_RF_ VCO, VDDA1P1_AUX_VCO, and VDDA1P1_CLOCK_ VCO pins. Place them as close as possible to the ADRV9008-2 device with the ground side of the bypass capacitor placed so that ground currents flow away from other power pins and the bypass capacitors, if at all possible.
2. Connect a $14.3 \mathrm{k} \Omega$ resistor to the RBIAS pin (C14). This resistor must have a $1 \%$ tolerance.
3. Pull the TEST pin (J6) to ground for normal operation. The device has support for JTAG boundary scan, and this pin is used to access that function. Refer to the JTAG Boundary Scan section for JTAG boundary scan information.
4. Pull the RESET pin (J4) high with a $10 \mathrm{k} \Omega$ resistor to VDD_INTERFACE for normal operation. To reset the device, drive the RESET pin low.

When routing analog signals such as GPIO_3p3_x/Auxiliary DAC x or AUXADC_x, it is recommended to route them away from the digital section (Row H through Row P). Do not cross the analog section of the ADRV9008-2 highlighted by a reddotted line in Figure 276 by any digital signal routing.

When routing digital signals from rows H and below, it is important to route them away from the analog section (Row A through Row G). Do not cross the analog section of the ADRV9008-2 highlighted by a red-dotted line in Figure 276 by any digital signal routing.

## RF AND JESD204B TRANSMISSION LINE LAYOUT RF Routing Guidelines

The ADRV9008-2W/PCBZ use microstrip type lines for observation receiver and transmitter RF traces. In general, Analog Devices, Inc. does not recommend using vias to route RF traces unless a direct line route is not possible.


Figure 276. Auxiliary ADC, Analog, and Digital GPIO Signals Routing Guidelines

Differential lines from the balun to the observation receiver and transmitter pins need to be as short as possible. Make the length of the single-ended transmission line also short to minimize the effects of parasitic coupling. It is important to note that these traces are the most critical when optimizing performance and are, therefore, routed before any other routing. These traces have the highest priority if trade-offs are needed.
Figure 277 and Figure 278 show pi matching networks on the single-ended side of the baluns. The observation receiver front end is dc biased internally, so the differential side of the balun is ac-coupled. The system designer can optimize the RF performance with a proper selection of the balun, matching components, and ac coupling capacitors. The external LO traces and the REF_CLK_IN $\pm$ traces may require matching components as well to ensure optimal performance.
All the RF signals mentioned previously must have a solid ground reference under each trace. Do not run any of the critical traces over a section of the reference plane that is discontinuous. The ground flood on the reference layer must extend all the way to the edge of the board. This flood length ensures signal integrity for the SMA launch when an edge launch connector is used.

Refer to the RF Port Interface Information section for more information on RF matching recommendations for the device.


Figure 277. Pi Network Matching Components Available on Transmitter Outputs


Figure 278. Pi Network Matching Components Available on Observation Receiver Inputs

## Data Sheet

## ADRV9008-2

## Transmitter Balun DC Feed Supplies

Each transmitter requires approximately 200 mA supplied through an external connection. On the ADRV9008-2 and ADRV9009 evaluation boards, bias voltages are supplied at the dc feed of the baluns. Layout of both boards allows the use of external chokes to provide a 1.8 V power domain to the ADRV9008-2 outputs. This configuration is useful in scenarios where a balun used at the transmitter output is not capable of
conducting the current necessary for the transmitter outputs to operate. To reduce switching transients when attenuation settings change, power the balun dc feed or transmitter output chokes directly by the 1.8 V plane. Design the geometry of the 1.8 V plane so that each balun supply or each set of two chokes is isolated from the other. This geometry can affect tansmitter to transmitter isolation. Figure 279 shows the layout configuration used on the ADRV9008-2W/PCBZ.


Figure 279. Transmitter Power Supply Planes (VDDA1P8_TX) on the ADRV9008-2W/PCBZ

Both the positive and negative transmitter pins must be biased with 1.8 V . This biasing is accomplished on the evaluation board through dc capacitors chokes and decoupling capacitors, as shown in Figure 280. Match both chokes and their layout to avoid potential current spikes. A difference in parameters between both chokes can cause unwanted emission at transmitter outputs. Place the decoupling capacitors that are near the transmitter balun as close as possible to the dc feed of the balun or the ground pin. Make orientation of the capacitor perpendicular to the device so that the return current forms as small a loop as possible with the ground pins surrounding the transmitter input. A combination network of capacitors is used to provide a wideband and low impedance ground path and helps to eliminate transmitter spectrum spurs and dampens the transients.


Figure 280. Transmitter DC Chokes and Balun Feed Supply

## JESD204B Trace Routing Recommendations

The ADRV9008-2 transceiver uses the JESD204B, high speed serial interface. To ensure optimal performance of this interface, keep the differential traces as short as possible by placing the ADRV9008-2 as close as possible to the FPGA or BBP, and route the traces directly between the devices. Use a PCB material with a low dielectric constant ( $<4$ ) to minimize loss. For distances greater than 6 inches, use a premium PCB material, such as RO4350B or RO4003C.

## Routing Recommendations

Route the differential pairs on a single plane using a solid ground plane as a reference on the layers above and/or below these traces.
All JESD204B lane traces must be impedance controlled to achieve $50 \Omega$ to ground. It is recommended that the differential pair be coplanar and loosely coupled. An example of a typical configuration is a 5 mil trace width and 15 mil edge to edge spacing, with the trace width maximized as shown in Figure 281.
Match trace widths with pin and ball widths while maintaining impedance control. If possible, use 1 oz . copper trace widths of at least $8 \mathrm{mil}(200 \mu \mathrm{~m})$. The coupling capacitor pad size must match JESD204B lane trace widths If trace width does not match pad size, use a smooth transition between different widths.

The pad area for all connector and passive component choices must be minimized due to a capacitive plate effect that leads to problems with signal integrity.
Reference planes for impedance controlled signals must not be segmented or broken for the entire length of a trace.
The REF_CLK_IN $\pm$ signal trace and the SYSREF signal trace are impedance controlled for characteristic impedence $\left(\mathrm{Z}_{0}\right)=$ $50 \Omega$.

## Stripline Transmission Lines vs. Microstrip Transmission Lines

Stripline transmission lines have less singal loss and emit less electromagnetic interference than microstrip transmission lines. However, stripline transmission lines require the use of vias that add line inductance, increasing the difficulty of controlling the impedance.
Microstrip transmission lines are easier to implement if the component placement and density allow routing on the top layer. Microstrip transmission lines make controlling the impedance easier.

If the top layer of the PCB is used by other circuits or signals, or if the advantages of stripline transmission lines are more desirable over the advantages of microstrip transmission lines, follow these recommendations:

- Minimize the number of vias.
- Use blind vias where possible to eliminate via stub effects, and use micro vias to minimize via inductance.
- When using standard vias, use a maximum via length to minimize the stub size. For example, on an 8-layer board, use Layer 7 for the stripline pair.
- Place a pair of ground vias in close proximity to each via pair to minimize the impedance discontinuity.
Route the JESD204B lines on the top side of the board as a differential $100 \Omega$ pair (microstrip). For the ADRV90082W/PCBZ, the JESD204B differential signals are routed on inner layers of the board (Layer 5 and Layer 10) as differential
$100 \Omega$ pairs (stripline). To minimize potential coupling, these signals are placed on an inner layer using a via embedded in the component footprint pad where the ball connects to the PCB. The ac coupling capacitors ( 100 nF ) on these signals are placed near the connector and away from the chip to minimize coupling. The JESD204B interface can operate at frequencies of up to 12 GHz . Ensure that signal integrity from the chip to the connector is maintained.


## ISOLATION TECHNIQUES USED ON THE ADRV9008-2W/PCBZ

## Isolation Goals

Significant isolation challenges were overcome in designing the ADRV9008-2W/PCBZ. The following isolation requirements are used to accurately evaluate the ADRV9008-2 transceiver performance:

- Transmitter to transmitter, 75 dB out to 6 GHz
- Transmitter to observation receiver, 65 dB out to 6 GHz

To meet these isolation goals with significant margin, isolation structures are introduced.
Figure 282 shows the isolation structures used on the ADRV9008$2 \mathrm{~W} / \mathrm{PCBZ}$. These structures consist of a combination of slots and square apertures. These structures are present on every copper layer of the PCB stack. The advantage of using square apertures is that signals can be routed between the openings without affecting the isolation benefits of the array of apertures. When using these isolation structures, make sure to place ground vias around the slots and apertures.


Figure 281. Routing JESD204B, Differential A and Differential B Correspond to Differential Positive Signals or Negative Signals (One Differential Pair)


Figure 282. Isolation Structures on the ADRV9008-2W/PCBZ


Figure 283. Current Steering Vias Placed Next to Isolation Structures

Figure 283 outlines the methodology used on the ADRV90082W/PCBZ. When using slots, ground vias must be placed at the ends of the slots and along the sides of the slots. When using square apertures, at least one single ground via must be placed adjacent to each square. These vias must be through-hole vias from the top to the bottom layer. The function of these vias is to steer return current to the ground planes near the apertures.
For accurate slot spacing and square apertures layout, use simulation software when designing a PCB for the ADRV9008-2 transceiver. Spacing between square apertures must be no more than $1 / 10$ of a wavelength. Calculate the wavelength using Equation 1:

$$
\begin{equation*}
\text { Wavelength }(\mathrm{m})=\frac{300}{\text { Frequency }(\mathrm{MHz}) \times \sqrt{E}} \tag{1}
\end{equation*}
$$

where $E_{R}$ is the dielectric constant of the isolator material. For RO4003C material, microstrip structure (+ air) $E_{R}=2.8$. For FR4370 HR material, stripline structure $E_{R}=4.1$.
For example, if the maximum RF signal frequency is 6 GHz , and $E_{R}=2.8$ for RO4003C material, microstrip structure (+ air), the minimum wavelength is approximately 29.8 mm .
To follow the $1 / 10$ wavelength spacing rule, square aperture spacing must be 2.98 mm or less.

## Isolation Between JESD204B Lines

The JESD204B interface uses eight line pairs that can operate at speeds of up to 12 GHz . When configuring the PCB layout, ensure these lines are routed according to the rules outlined in the JESD204B Trace Routing Recommendations section. In addition, use isolation techniques to prevent crosstalk between different JESD204B lane pairs.

Figure 284 shows a technique used on the ADRV9008-2W/PCBZ that involves via fencing. Placing ground vias around each JESD204B pair provides isolation and decreases crosstalk. The spacing between vias is 1.2 mm .
Figure 284 shows the rule provided in Equation 1 JESD204B lines are routed on Layer 5 and Layer 10 so that the lines use stripline structures. The dielectric material used in the inner layers of the ADRV9008-2W/PCBZ PCB is FR4-370HR.

For accurate spacing of the JESD204B fencing vias, use layout simulation software. Input the following data into Equation 1 to calculate the wavelength and square aperture spacing:

- The maximum JESD204B signal frequency is approximately 12 GHz .
- For FR4-370HR material, stripline structure, $\mathrm{E}_{\mathrm{R}}=4.1$, the minimum wavelength is approximately 12.4 mm .

To follow the $1 / 10$ wavelength spacing rule, spacing between vias must be 1.24 mm or less. The minimum spacing recommendation according to transmission line theory is $1 / 4$ wavelength.

Figure 284. Via Fencing Around JESD204B Lines, PCB Layer 10

## RF PORT INTERFACE INFORMATION

This section details the RF transmitter and observation receiver interfaces for optimal device performance. This section also includes data for the anticipated ADRV9008-2 RF port impedance values and examples of impedance matching networks used in the evaluation platform. This section also provides information on board layout techniques and balun selection guidelines.

The ADRV9008-2 is a highly integrated transceiver with transmit and observation (DPD) receive signal chains. External impedance matching networks are required on transmitter and observation receiver ports to achieve performance levels indicated on the data sheet.

Analog Devices recommends the use of simulation tools in the design and optimization of impedance matching networks. To achieve the closest match between computer simulated results and measured results, accurate models of the board environment, surface-mount device (SMD) components (including baluns and filters), and ADRV9008-2 port impedances are required.

## RF Port Impedance Data

This section provides the port impedance data for all transmitters and observation receivers in the ADRV9008-2 integrated transceiver. Please note the following:

- Zo is defined as $50 \Omega$.
- The ADRV9008-2 ball pads are the reference plane for this data.
- Single-ended mode port impedance data is not available. However, a rough assessment is possible by taking the differential mode port impedance data and dividing both the real and imaginary components by 2 .
- Contact Analog Devices applications engineering for the impedance data in Touchstone format.
m21
FREQUENCY $=100 \mathrm{MHz}$
$\mathrm{S}(1,1)=0.143 /-7.865$
IMPEDANCE $=66.439-\mathrm{j} 2.654$
m22
FREQUENCY $=300 \mathrm{MHz}$
$\mathrm{S}(1,1)=0.141 /-25.589$
IMPEDANCE $=64.063-\mathrm{j} 7.987$
m23
FREQUENCY $=500 \mathrm{MHz}$
S(1,1) $=0.145 /-42.661$
IMPEDANCE $=60.623-\mathrm{j} 12.201$
m24
FREQUENCY $=1 \mathrm{GHz}$
S(1,1) $=0.164 /-84.046$
IMPEDANCE $=49.000+\mathrm{j} 16.447$
m25
FREQUENCY $=2 \mathrm{GHz}$
S(1,1) $=0.247 I-155.186$
IMPEDANCE $=31.131-\mathrm{j} 6.860$


FREQUENCY $(0.000 \mathrm{~Hz}$ TO 6.000 Hz$)$
Figure 285. Transmitter 1 and Transmitter 2 SEDZ and Parallel Equivalent Differential Impedance (PEDZ) Data


Figure 286. Observation Receiver 1 and Observation Receiver 2 SEDZ and PEDZ Data


Figure 287. RF_EXT_LO_I/O $\pm$ SEDZ and PEDZ Data


Figure 288. REF_CLK_IN $\pm$ SEDZ and PEDZ Data, On Average, the Real Part of the Parallel Equivalent Differential Impedance $\left(R_{P}\right)=\sim 70 \mathrm{k} \Omega$

## ADRV9008-2

## Advanced Design System (ADS) Setup Using the DataAccessComponent and SEDZ File

Analog Devices supplies the port impedance as an .slp file that can be downloaded from the ADRV9008-2 product page. This format allows simple interfacing to the ADS by using the DataAccessComponent. In Figure 289, Term 1 is the singleended input or output, and Term 2 is the differential input or output RF port on the device. The pi on the single-ended side and the differential pi configuration on the differential side allow maximum flexibility in designing matching circuits. The pi configuration is suggested for all design layouts because the pi configuration can step the impedance up or down as needed with appropriate component population.

The mechanics of setting up a simulation for impedance measurement and impedance matching is as follows:

1. The DataAccessComponent block reads the RF port .slp file. This file is the device RF port reflection coefficient.
2. The two equations convert the RF port reflection coefficient to a complex impedance. The result is the RX_SEDZ variable.
3. The RF port calculated complex impedance (RX_SEDZ) is used to define the Term 2 impedance.
4. Term 2 is used in a differential mode, and Term 1 is used in a single-ended mode.
5. Setting up the simulation this way allows one to measure the input reflection (S11), output reflection (S22), and through reflection (S21) of the three-port system without complex math operations within the display page.

For the highest accuracy, electromagnetic momentum (EM) modelling result of the PCB artwork, S11, S22, and S21 of the matching components and balun must be used in the simulations.

## Transmitter Bias and Port Interface

This section considers the dc biasing of the ADRV9008-2 transmitter outputs and how to interface to each transmitter port. The ADRV9008-2 transmitters operate over a range of frequencies. At full output power, each differential output side draws approximately 100 mA of dc bias current. The transmitter outputs are dc biased to a 1.8 V supply voltage using either RF chokes (wire wound inductors) or a transformer center tap connection.

Careful design of the dc bias network is required to ensure optimal RF performance levels. When designing the dc bias network, select components with low dc resistance to minimize the voltage drop across the series parasitic resistance element with either of the suggested dc bias schemes suggested in Figure 290. The $\mathrm{R}_{\mathrm{DCR}}$ resistors indicate the parasitic elements. As the impedance of the parasitics increases, the voltage drop ( $\Delta \mathrm{V}$ ) across the parasitic element increases, which causes the transmitter RF performance ( $\mathrm{P}_{\mathrm{o}, 1 \mathrm{~d}}, \mathrm{P}_{\mathrm{o}, \mathrm{max}}$, and so on) to degrade. The choke inductance $\left(\mathrm{L}_{\mathrm{C}}\right)$ must be at least $3 \times$ times higher than the load impedance at the lowest desired frequency so that it does not degrade the output power (see Table 10).

## Simple Port Impedance Matching Schematic



Figure 289. Simulation Setup in ADS with SEDZ.s1p Files and DataAccessComponent
Table 10. Sample Wire Wound DC Bias Choke Resistance vs. Size vs. Inductance

| Inductance (nH) | Resistance (Size: 0603)(्) | Resistance (Size: 1206) ( $\mathbf{\Omega})$ |
| :--- | :--- | :--- |
| 100 | 0.10 | 0.08 |
| 200 | 0.15 | 0.10 |
| 300 | 0.16 | 0.12 |
| 400 | 0.28 | 0.14 |
| 500 | 0.45 | 0.15 |
| 600 | 0.52 | 0.20 |

The recommended dc bias network is shown in Figure 291. This network has fewer parasitics and fewer total components.
Figure 292 through Figure 295 identify four basic differential transmitter output configurations. Except in cases in which impedance is already matched, impedence matching networks (balun single-ended port) are required to achieve optimum device performance. In applications in which the transmitter is not connected to another circuit that requires or can tolerate dc bias on the transmitter outputs, the transmitter outputs must be ac-coupled because of the dc bias voltage applied to the differential output lines of the transmitter.
The recommended RF transmitter interface is shown in Figure 290 to Figure 295, featuring a center tapped balun. This configuration offers the lowest component count of the options presented.

Descriptions of the transmitter port interface schemes are as follows:

- In Figure 292, the center tapped transformer passes the bias voltage directly to the transmitter outputs.
- In Figure 293, RF chokes bias the differential transmitter output lines. Additional coupling capacitors $\left(\mathrm{C}_{\mathrm{C}}\right)$ are added in the creation of a transmission line balun.
- In Figure 294, RF chokes are used to bias the differential transmitter output lines and connect to a transformer.
- In Figure 295, RF chokes bias the differential output lines that are ac-coupled to the input of a driver amplifier.

If a transmitter balun that requires a set of external dc bias chokes is selected, careful planning is required. It is necessary to find the optimum compromise between the choke physical size, choke dc resistance, and the balun low frequency insertion loss. In commercially available dc bias chokes, resistance decreases as size increases. As choke inductance increases, resistance increases. It is undesirable to use physically small chokes with high inductance because small chokes exhibit the greatest resistance. For example, the voltage drop of a $500 \mathrm{nH}, 0603$ choke at 100 mA is roughly 50 mV .


Figure 290. RF DC Bias Configurations Showing Parasitic Losses Due to Wire Wound Chokes


Figure 291. RF DC Bias Configurations Showing Parasitic Losses Due to Center Tapped Transformers


Figure 292. RF Transmitter Interface Configurations


Figure 293. RF Transmitter Interface Configurations


Figure 294. RF Transmitter Interface Configurations


Figure 295. RF Transmitter Interface Configurations

## ADRV9008-2

## General Observation Receiver Path Interface

The ADRV9008-2 has two observation, or DPD, receivers (Observation Receiver 1 and Observation Receiver 2). The observation receivers can support up to 450 MHz bandwidth. The observation receiver channels are designed for differential use.

The ADRV9008-2 differential signals of the observation receivers interface to an integrated mixer. The mixer input pins have a dc bias of approximately 0.7 V and may need to be ac-coupled, depending on the common-mode voltage level of the external circuit.
Important considerations for the observation receiver port interface are as follows:

- The device to be interfaced (filter, balun, transmit/receive (T/R) switch, external low noise amplifier (LNA), external PA, and so on).
- The observation receiver maximum safe input power is 23 dBm (peak).
- The observation receiver optimum dc bias voltage is 0.7 V bias to ground.
- The board design (reference planes, transmission lines, impedance matching, and so on).

Figure 296 and Figure 297 show possible differential observation receiver port interface circuits. The options in Figure 296 and Figure 297 are valid for all observation receiver inputs operating in differential mode, although only the Observation Receiver 1 signal names are indicated. Impedance matching may be necessary to obtain the performance levels.
Given wide RF bandwidth applications, SMD balun devices function well. Decent loss and differential balance are available in a relatively small $(0603,0805)$ package.


Figure 296. Differential Observation Receiver Interface Using a Transformer


Figure 297. Differential Observation Receiver Interface Using a Transmission Line Balun

## Impedance Matching Network Example

Impedance matching networks are required to achieve the ADRV9008-2 data sheet performance levels. This section provides a description of matching network topologies and components used on the ADRV9008-2W/PCBZ.

Device models, board models, and balun and SMD component models are required to build an accurate system level simulation. The board layout model can be obtained from an EM simulator. The balun and SMD component models can be obtained from the device vendors or built locally. Contact Analog Devices applications engineering for ADRV9008-2 modeling details.

The impedance matching network provided in this section is not evaluated in terms of mean time to failure (MTTF) in high volume production. Consult with component vendors for longterm reliability concerns. Consult with balun vendors to determine appropriate conditions for dc biasing.
Figure 299 and Figure 300 show that in a generic port impedance matching network, the shunt or series elements may be a resistor, inductor, or capacitor.

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## ADRV9008-2

RF OUTPUT 1


RF OUTPUT 2


Figure 299. Transmitter 1 and Transmitter 2 Generic Matching Network Topology

## Data Sheet ADRV9008-2



Figure 300. Observation Receiver 1 and Observation Receiver 2 Generic Matching Network Topology

## ADRV9008-2

Table 11 and Table 12 show the selected balun and component values used for the matching network sets. Refer to the ADRV9008-2 schematics for a wideband matching example that operates across the entire device frequency range with somewhat reduced performance.

The RF matching used in the ADRV9008-2W/PCBZ allows the ADRV9008-2 to operate across the entire chip frequency range with slightly reduced performance.

Table 11. Observation Receiver 1 and Observation Receiver 2 Evaluation Board Matching Components for Frequency Band 75 MHz to 6000 MHz

| Component | Value |
| :--- | :--- |
| C215, C22 | Do not install (DNI) |
| R216, R223 | $0 \Omega$ |
| C217, C224 | DNI |
| C250, C251 | 18 pF |
| C218, C225 | DNI |
| R219/R220, R226/R227 | $0 \Omega$ |
| C221, C228 | DNI |
| T205, T207 | Mini circuits TCM1-83X+ |

Table 12. Transmitter 1 and Transmitter 2 Evaluation Board Matching Components ${ }^{1}$ for Frequency Band 75 MHz to 6000 MHz

| Component | Value |
| :--- | :--- |
| C314, C322 | DNI |
| R309, R312 | $0 \Omega$ |
| C312, C320 | DNI |
| C337, C336 | 18 pF |
| C338, C342 | DNI |
| R307/R308, R310/R311 | $0 \Omega$ |
| C339, C341 | DNI |
| T302,T303 | Mini circuits TCM1-83X+ |

[^4]
## OUTLINE DIMENSIONS



COMPLIANT TO JEDEC STANDARDS MO-275-GGAB-1.
Figure 301. 196-Ball Chip Scale Package Ball Grid Array [CSP_BGA] (BC-196-13)
Dimensions shown in millimeters

## ORDERING GUIDE

| Model $^{1}$ | Temperature Range $^{\mathbf{2}}$ | Package Description $_{\text {Package Option }}$ |  |
| :--- | :--- | :--- | :--- |
| ADRV9008BBCZ-2 | $-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$ | 196 -Ball Chip Scale Package Ball Grid Array [CSP_BGA] | BC-196-13 |
| ADRV9008BBCZ-2REEL | $-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$ | 196 -Ball Chip Scale Package Ball Grid Array [CSP_BGA] | BC-196-13 |
| ADRV9008-2W/PCBZ |  | Pb-Free Evaluation Board, 75 MHz to 6000 MHz |  |

${ }^{1} Z=$ RoHS Compliant Part.
${ }^{2}$ See the Thermal Management section.


[^0]:    ${ }^{1}$ VDDA1P3 refers to all analog 1.3 V supplies, including: VDDA1P3_RF_SYNTH, VDDA1P3_BB, VDDA1P3_RX_RF, VDDA1P3_RX_TX, VDDA1P3_RF_VCO_LDO, VDDA1P3_RF_LO, VDDA1P3_DES, VDDA1P3_SER, VDDA1P3_CLOCK_SYNTH, VDDA1P3_CLOCK_VCO_LDO, VDDA1P3_AUX_SYNTH, and VDDA1P3_AUX_VCO_LDO.
    ${ }^{2}$ Test equipment phase noise performance limited.

[^1]:    ${ }^{1}$ VDDA1P3 refers to all analog 1.3 V supplies, including: VDDA1P3_RF_SYNTH, VDDA1P3_BB, VDDA1P3_RX_RF, VDDA1P3_RX_TX, VDDA1P3_RF_VCO_LDO, VDDA1P3_RF_LO, VDDA1P3_DES, VDDA1P3_SER, VDDA1P3_CLOCK_SYNTH, VDDA1P3_CLOCK_VCO_LDO, VDDA1P3_AUX_SYNTH, and VDDA1P3_AUX_VCO_LDO.

[^2]:    ${ }^{1}$ VDDA1P3 refers to all analog 1.3 V supplies, including: VDDA1P3_RF_SYNTH, VDDA1P3_BB, VDDA1P3_RX_RF, VDDA1P3_RX_TX, VDDA1P3_RF_VCO_LDO, VDDA1P3_RF_LO, VDDA1P3_DES, VDDA1P3_SER, VDDA1P3_CLOCK_SYNTH, VDDA1P3_CLOCK_VCO_LDO, VDDA1P3_AUX_SYNTH, and VDDA1P3_AUX_VCO_LDO.

[^3]:    ${ }^{1} \mathrm{~N} / \mathrm{A}$ means not applicable.

[^4]:    ${ }^{1}$ These matches provide VDDA1P8_TX to the TXx_OUT $\pm$ pins through the balun.

